

# Insights from Single Particle Spectroscopy of Plasmonic Nanostructures

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Department of Chemistry

Department of Electrical and Computer Engineering



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# Acknowledgements



## Collaborators:

Christy Landes (UIUC)

Naomi Halas (Rice)

Peter Nordlander (Rice)

Jen Dionne (Stanford)

Tim Lian (Emory)

Greg Hartland (Notre Dame)

Peter Rossky (Rice)

Martin Zanni (Wisconsin)

Sean Roberts (UT Austin)

Ben Levine (Stony Brook)

Wei-Shun Chang (UMass Dartmouth)

Many more...

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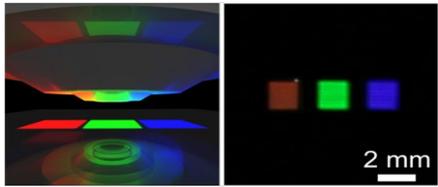
Ben Levine (Stony Brook)

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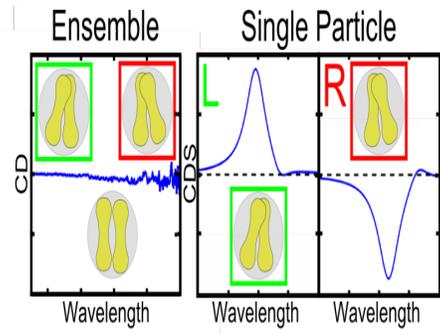
Many more...

# Link lab research: Single-particle spectroscopy of plasmonic nanostructures to remove heterogeneities in to gain detailed insight into structure-function relationships

## Plasmon Coupling in Nanoparticle Arrays



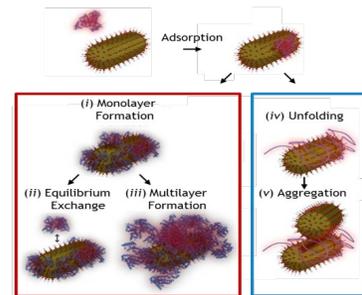
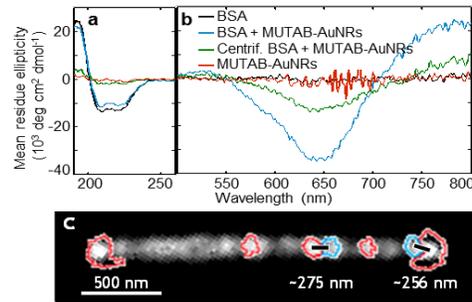
Aluminum Plasmonic Pixels  
ACS Nano 10, 1108 (2016)



Chiral Assemblies

ACS Nano 10, 6180 (2016)  
PNAS, 117, 16143 (2020)

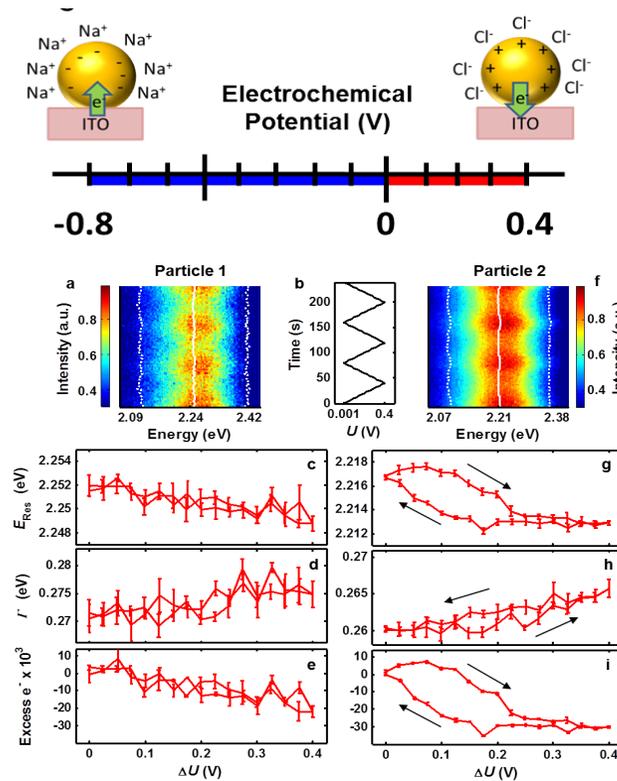
## Quantifying Nanoparticle-Protein Interactions



Composition and Structure of the Protein Corona

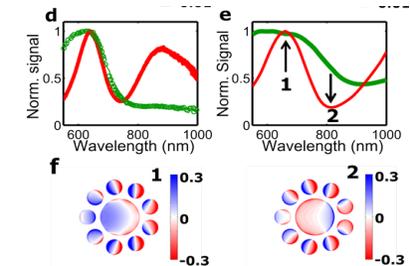
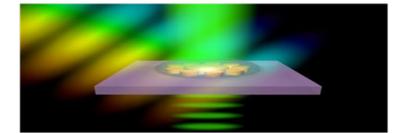
ACS Nano 10, 2103 (2016)  
Science 365, 1475 (2019)

## Single-Particle Electrochemistry

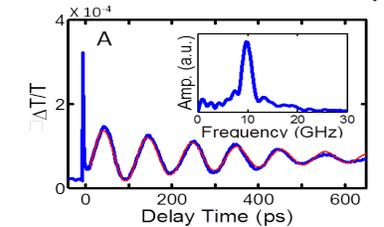


Optical read-out of particle charging  
J. Phys. Chem. B 118, 14047 (2014)  
J. Phys. Chem. Lett., 12, 2516 (2021)

## Energy Relaxation in Nanostructures



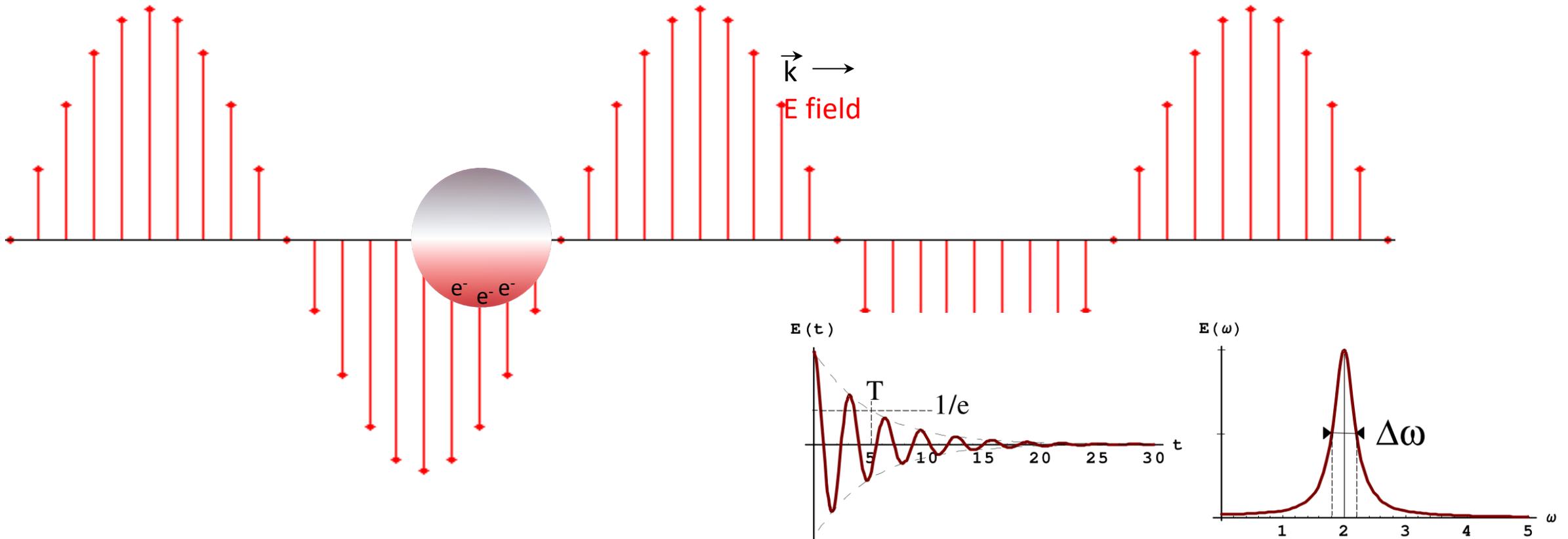
Photothermal Spectroscopy  
Nano Lett. 16, 6497 (2016)  
Nano Lett., 21, 5386 (2021)



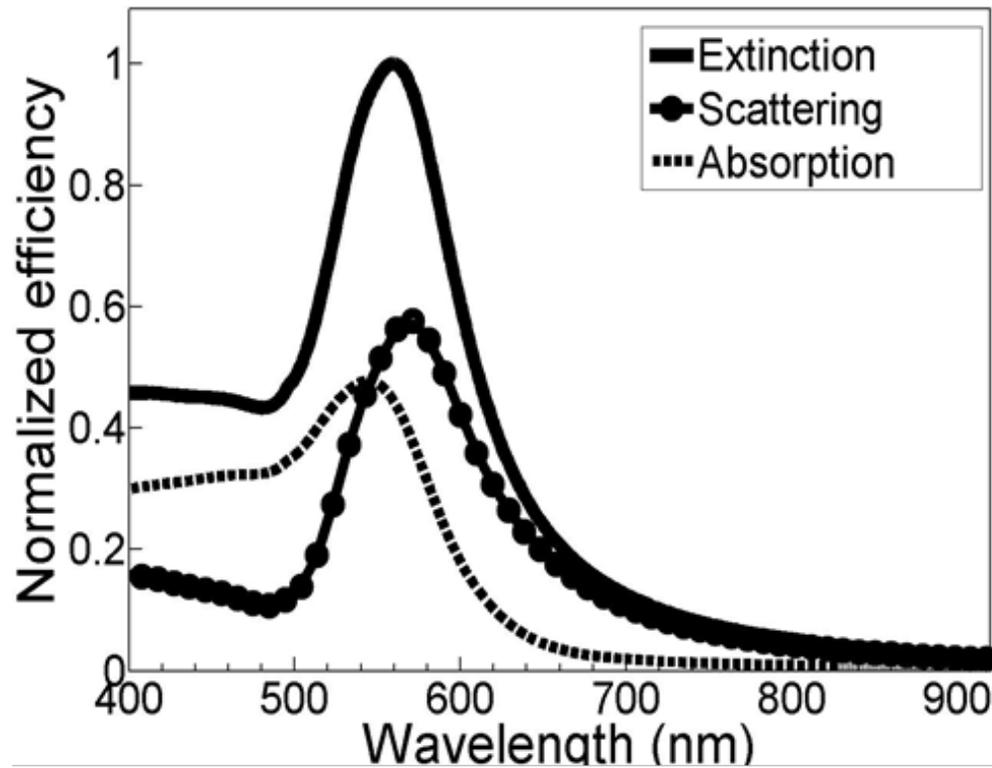
Ultrafast Relaxation Dynamics  
Nature Communications 2015

# Localized Surface Plasmons

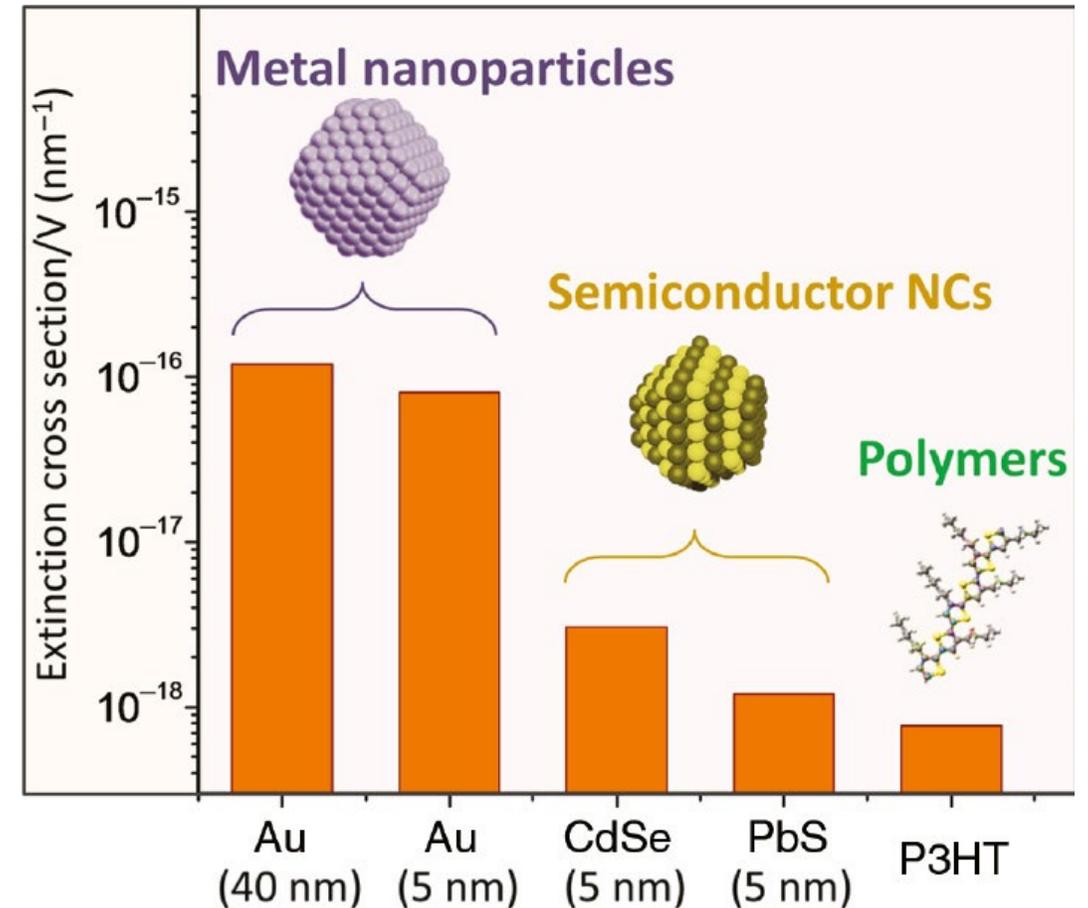
Coherent oscillation of conduction electrons coupled to incident electromagnetic field, described by an underdamped driven oscillator



# Converting photons to hot electrons with plasmons

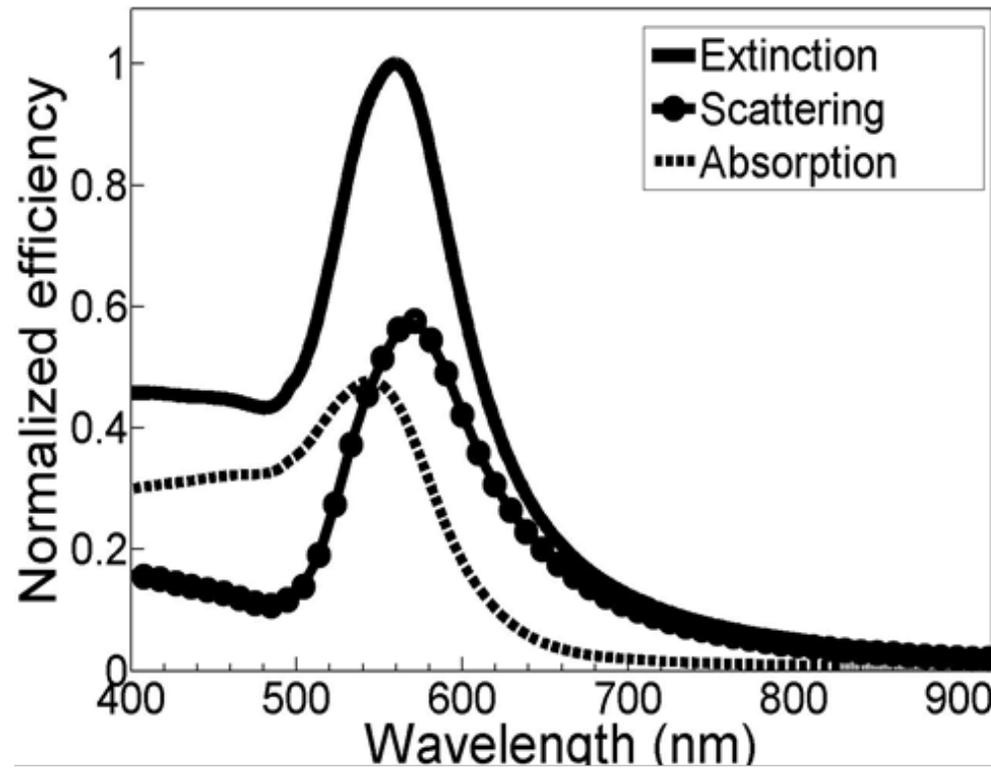


G. Mie, Ann. Phys. 25, 377 (1908)

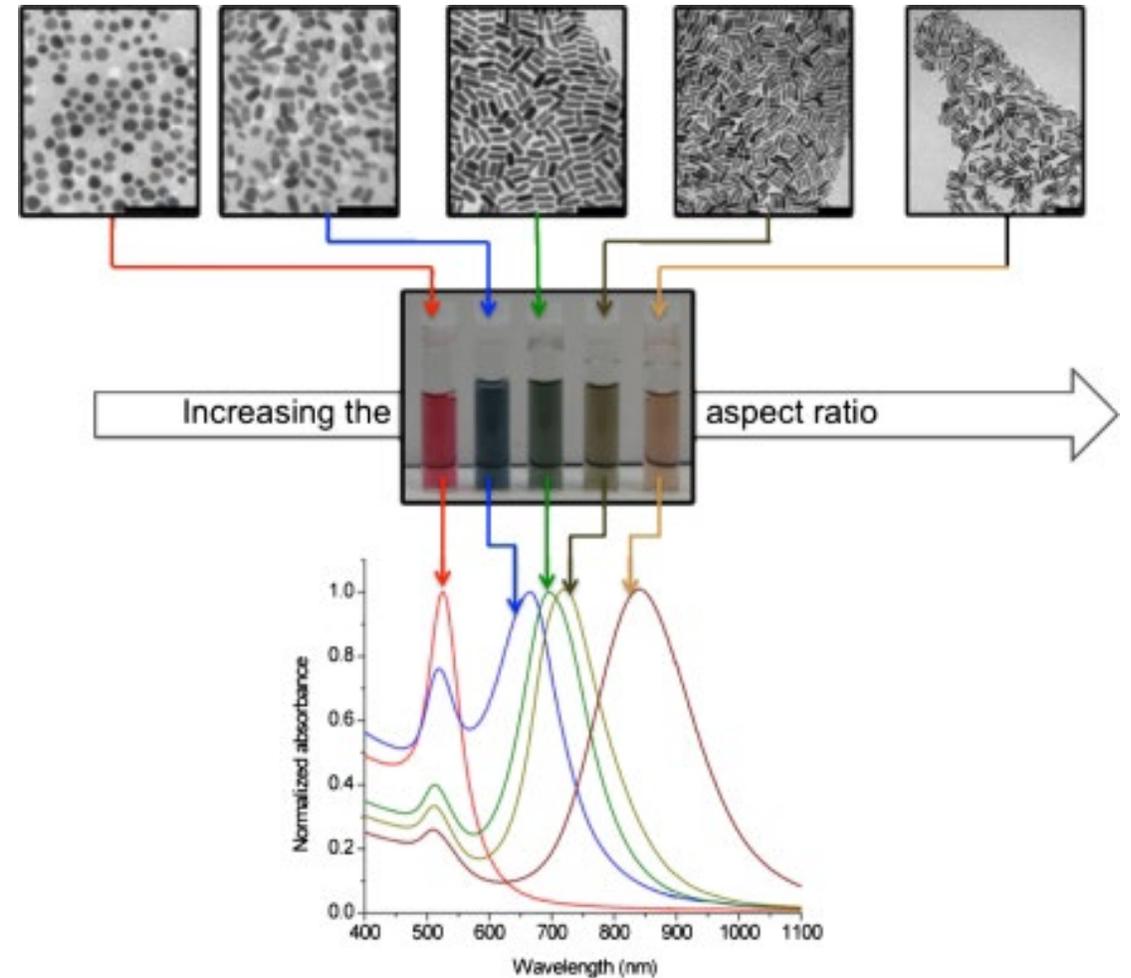


Kholmicheva, et al. *Nanophotonics* **2018**, 8, 613

# Converting photons to hot electrons with plasmons

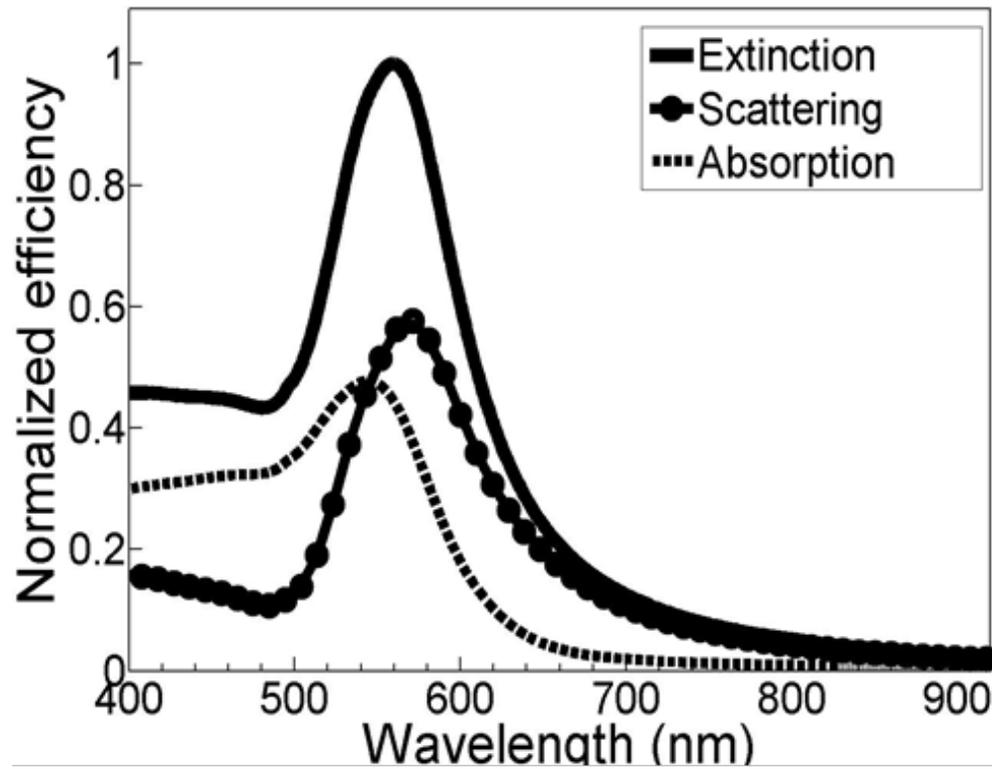


G. Mie, Ann. Phys. 25, 377 (1908)

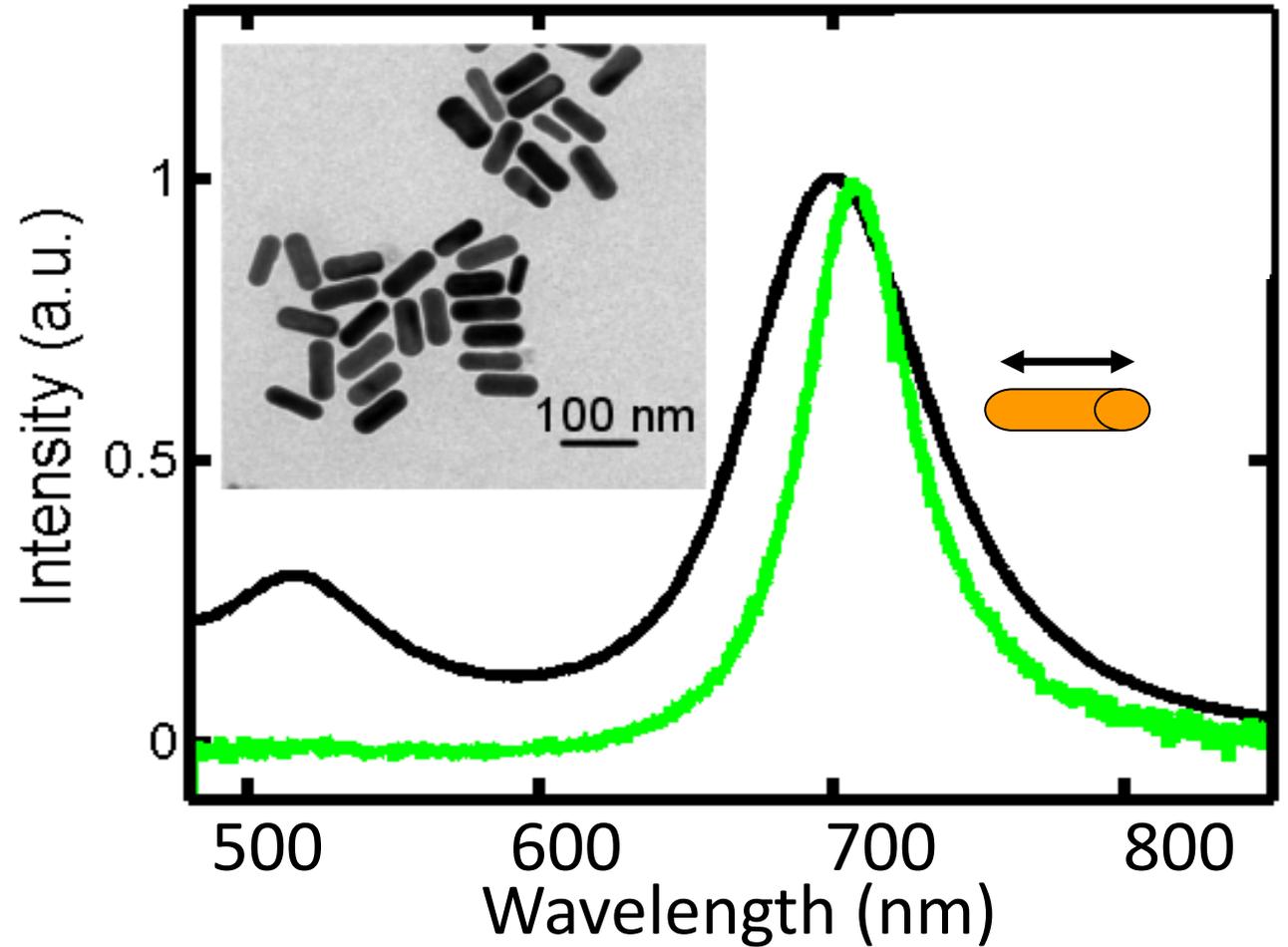


Alkilany, Murphy, *J. Nanopart. Res.* **2010**, *12*, 2313

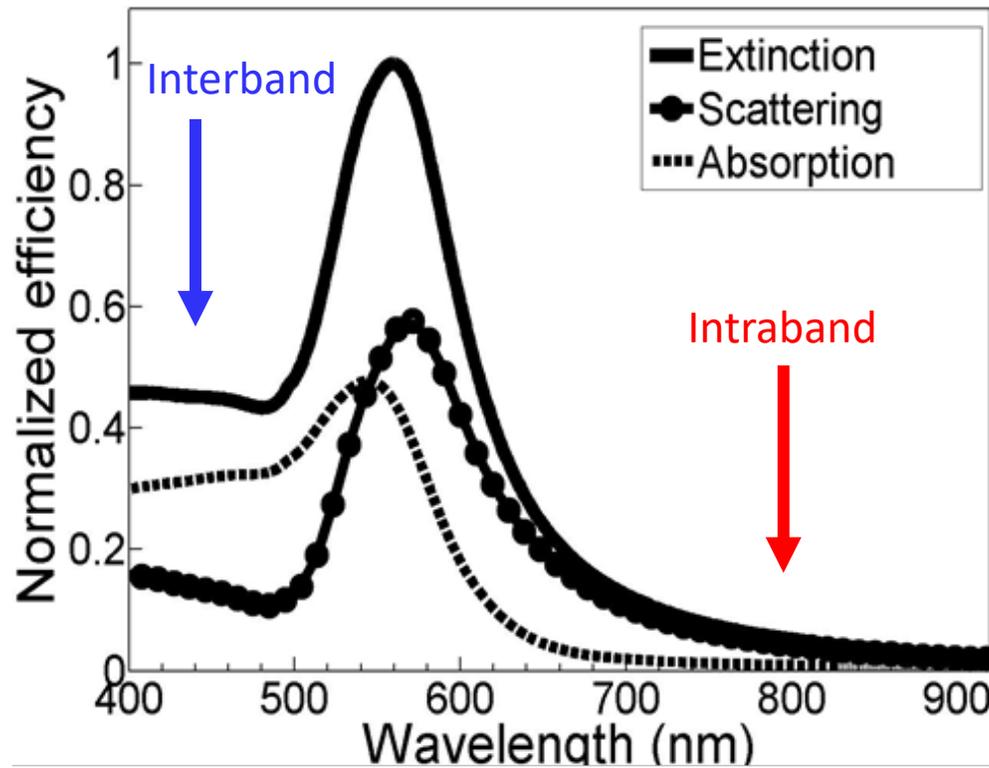
# Converting photons to hot electrons with plasmons



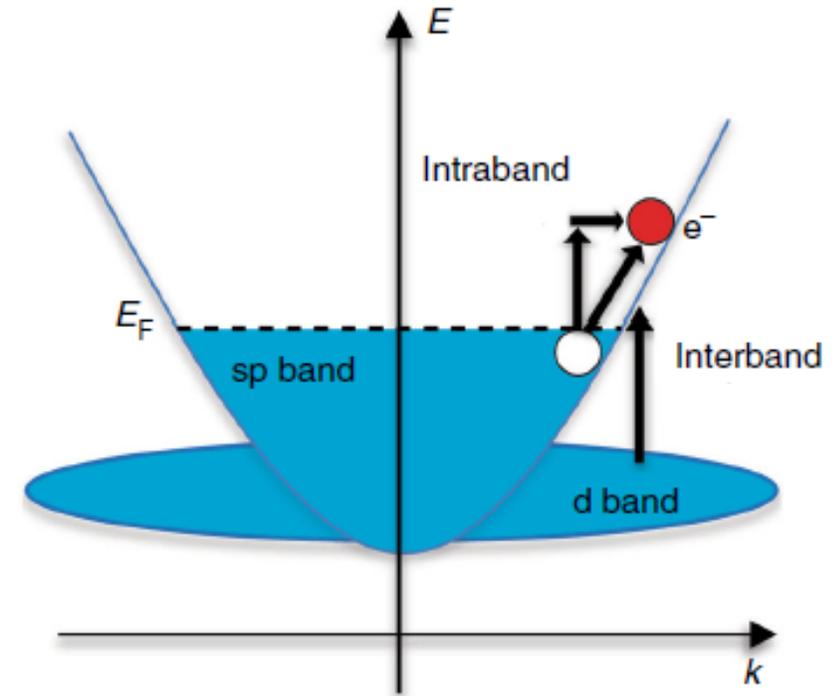
G. Mie, Ann. Phys. 25, 377 (1908)



# Photon absorption beyond plasmons



G. Mie, Ann. Phys. 25, 377 (1908)



Govorov, Wiederrecht, Gray, Harutyunyan, *Nat. Commun.* **2018**, 9, 1853

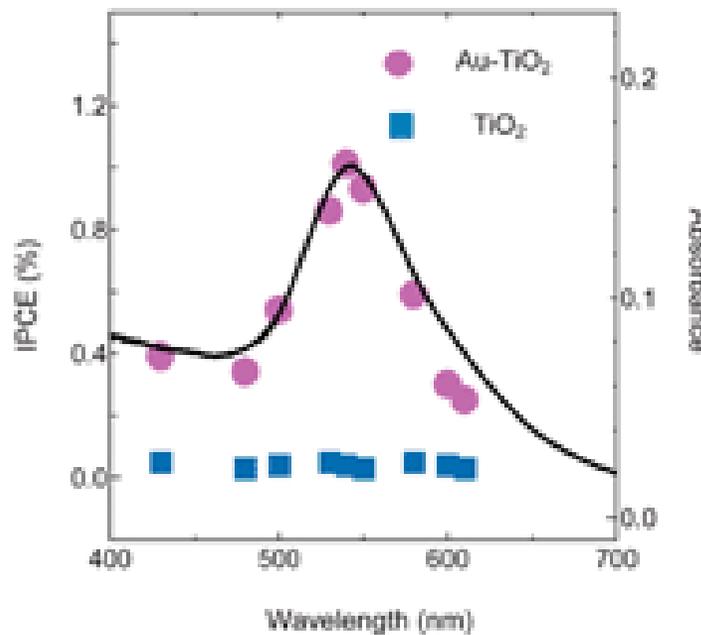
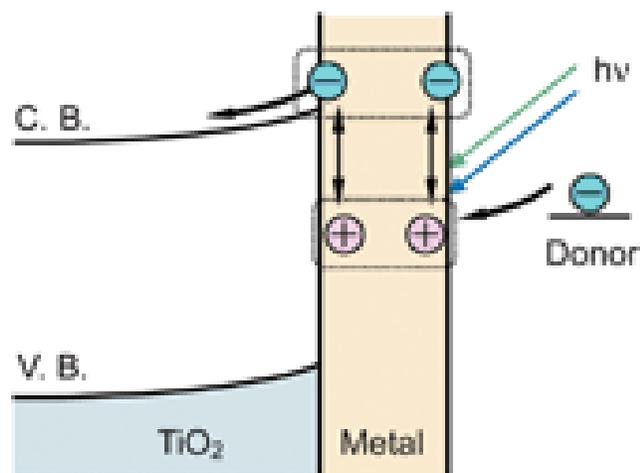
# Outline

- 1) Charge transfer at metal – semiconductor interfaces
- 2) Photoemission into water

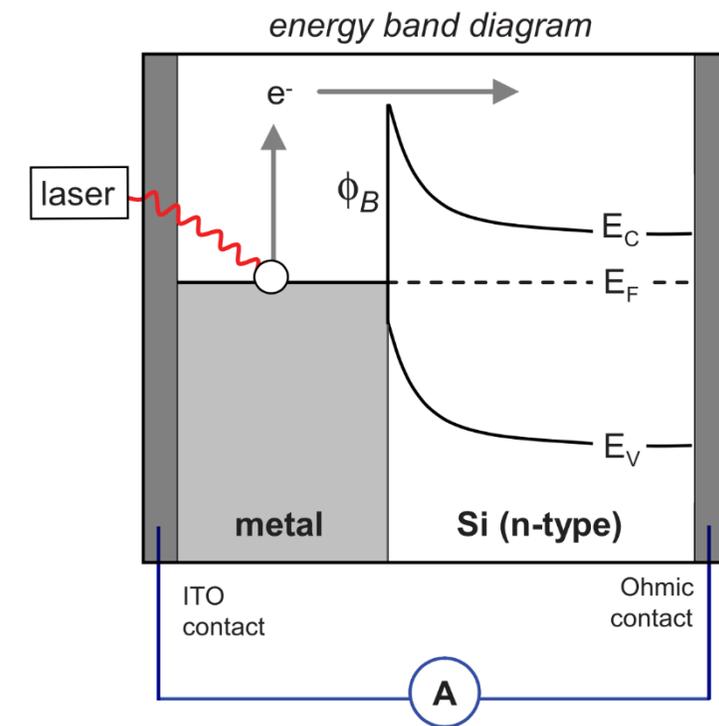
# Outline

- 1) Charge transfer at metal – semiconductor interfaces**
- 2) Photoemission into water

# Charge transfer at metal-semiconductor interfaces: Overcoming semiconductor bandgaps with lower photon energy plasmons



Tatsuma, *Chem. Commun.* **2004**, 1810



Nordlander, Halas, *Science* **2011**, 332, 702

**Advantage: Large tunable cross sections determining hot carrier energies; band offsets and not bandgaps are important**

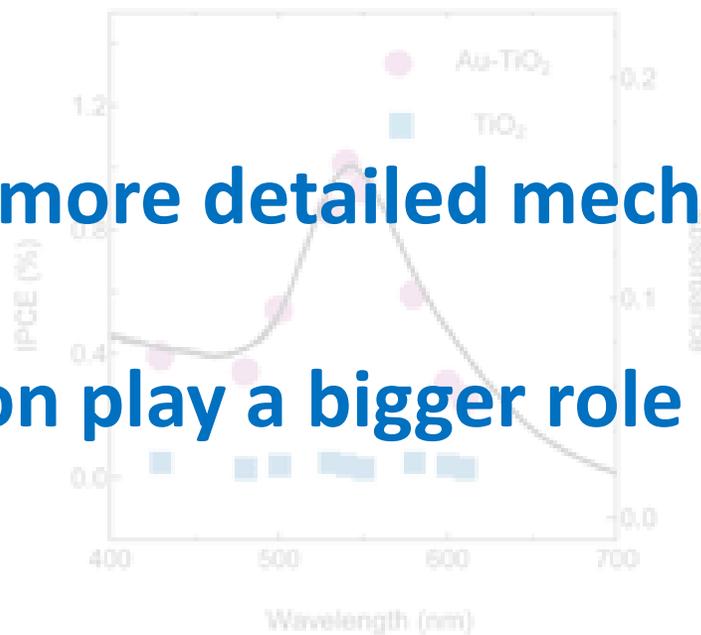
**Disadvantages: Often low yields**

# Charge transfer at metal-semiconductor interfaces: Overcoming semiconductor bandgaps with lower photon energy plasmons

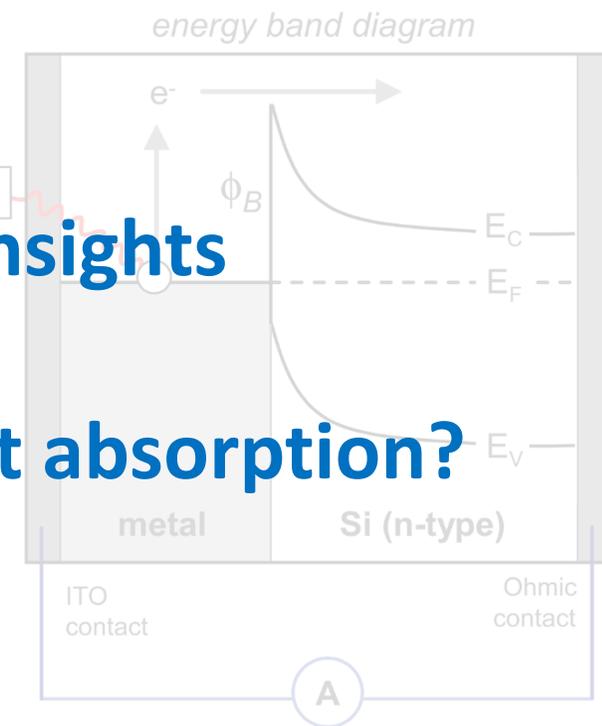


1) We need more detailed mechanistic insights

2) Does the plasmon play a bigger role than just absorption?



Tatsuma, *Chem. Commun.* 2004, 1810

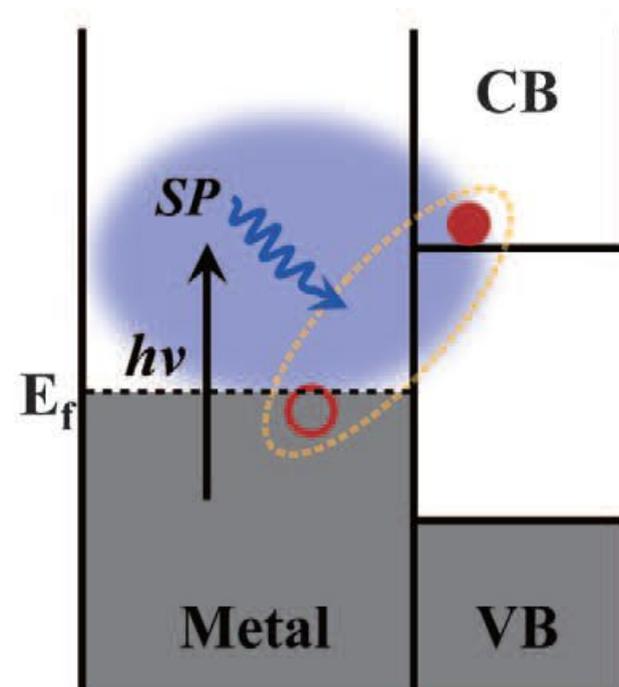
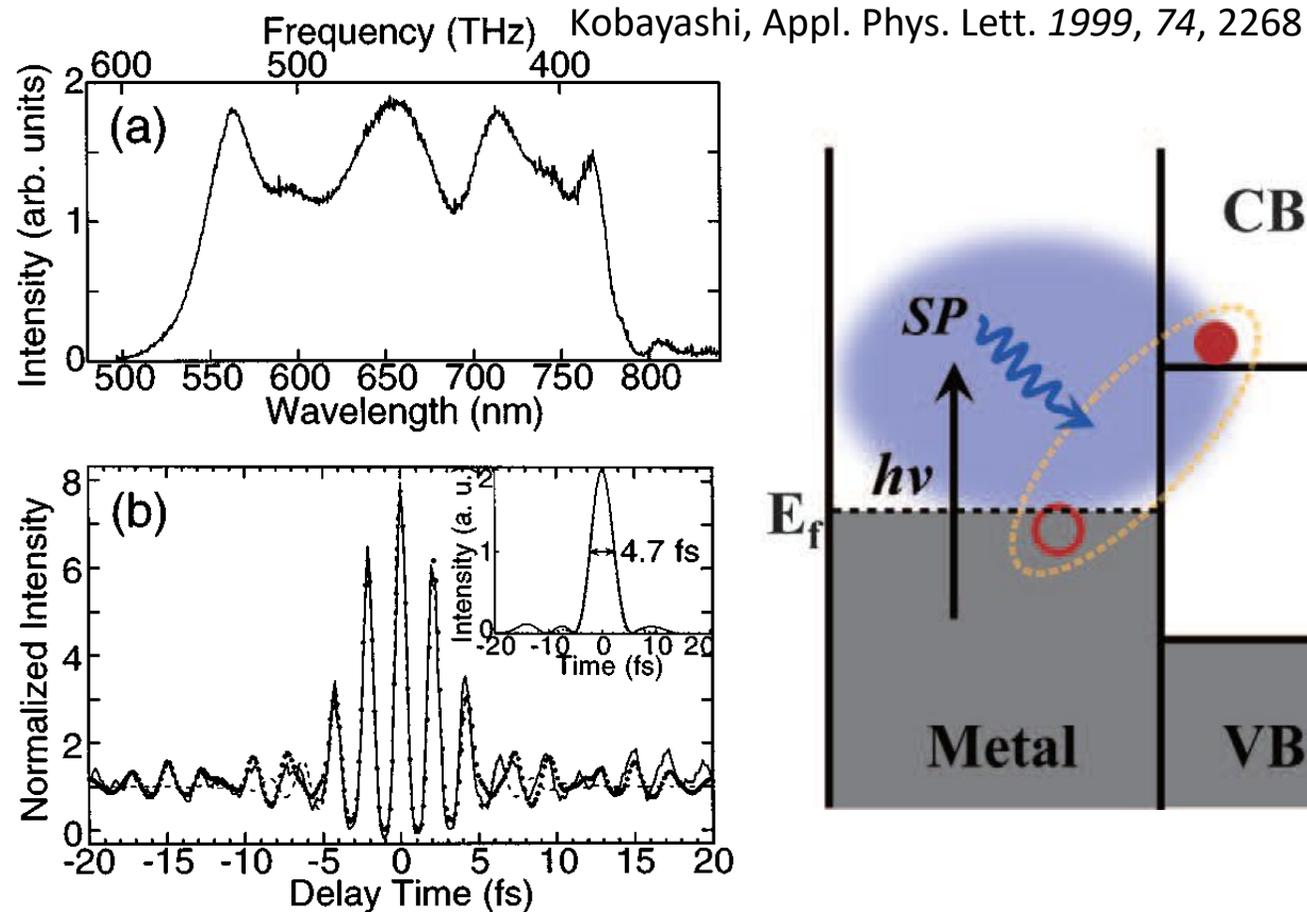
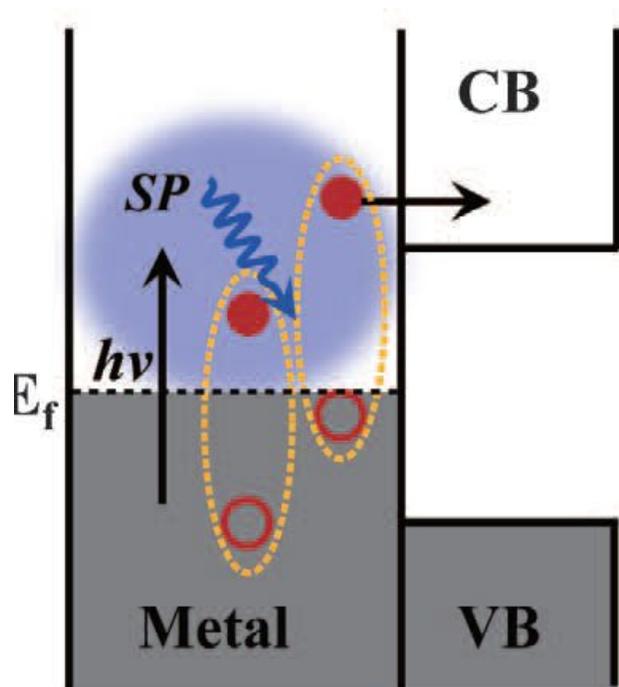


Nordlander, Halas, *Science* 2011, 332, 702

Advantage: Large tunable cross sections determining hot carrier energies; band offsets and not bandgaps are important

Disadvantages: Often low yields

# Plasmon induced charge transfer at metal-semiconductor interfaces – direct vs. indirect pathways



>24%  
efficiency

Lian, Science 2015, 349, 632

**BUT, how can we distinguish these mechanisms when both are expected to be less than 100 fs?**

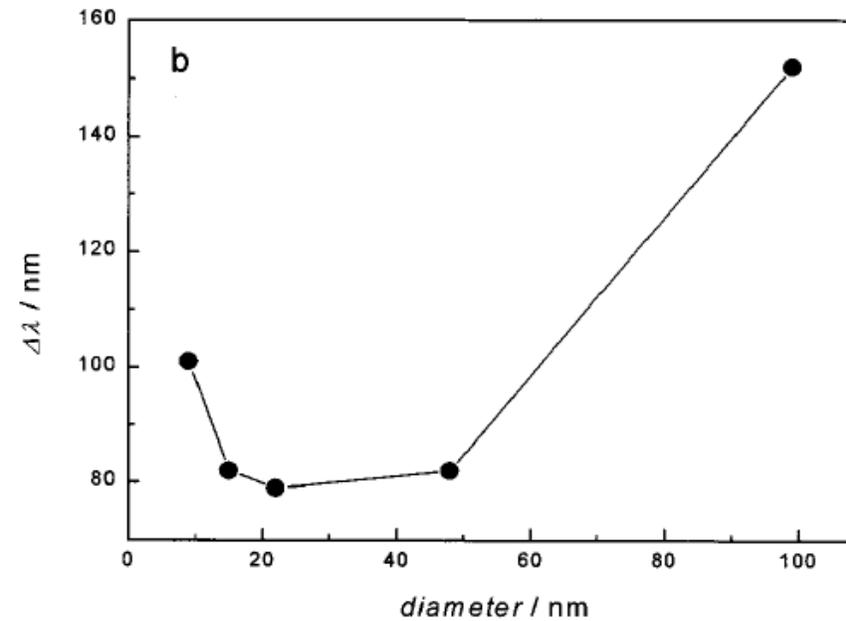
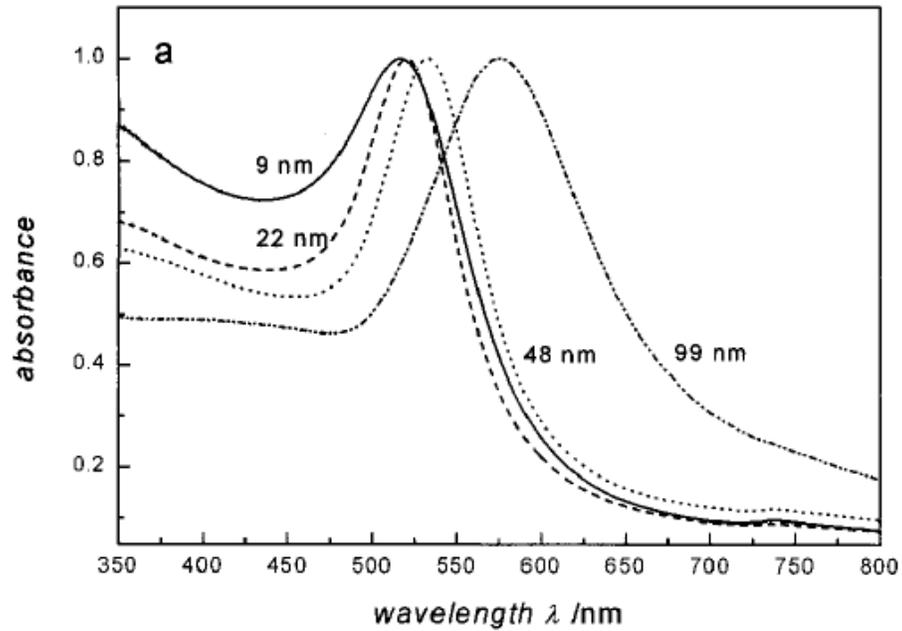
# Plasmon dephasing

4212

*J. Phys. Chem. B* 1999, 103, 4212–4217

## Size and Temperature Dependence of the Plasmon Absorption of Colloidal Gold Nanoparticles

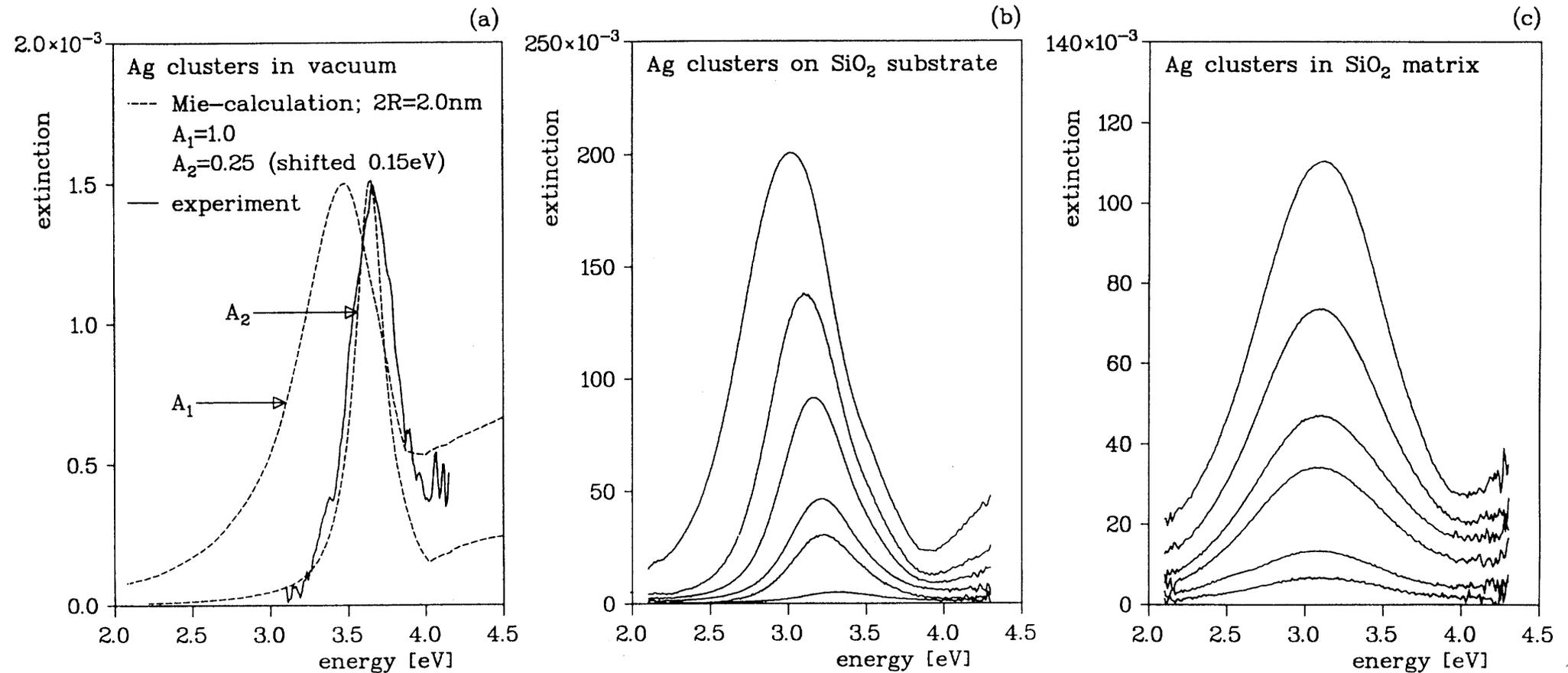
Stephan Link and Mostafa A. El-Sayed\*



$$\Gamma = \gamma_b + \Gamma_{\text{rad}} + \Gamma_{\text{surf}}$$

$$\Gamma_{\text{total}} = \gamma_b + 2\hbar\pi V + \frac{A_{\text{surf}} \cdot v_F}{l_{\text{eff}}}$$

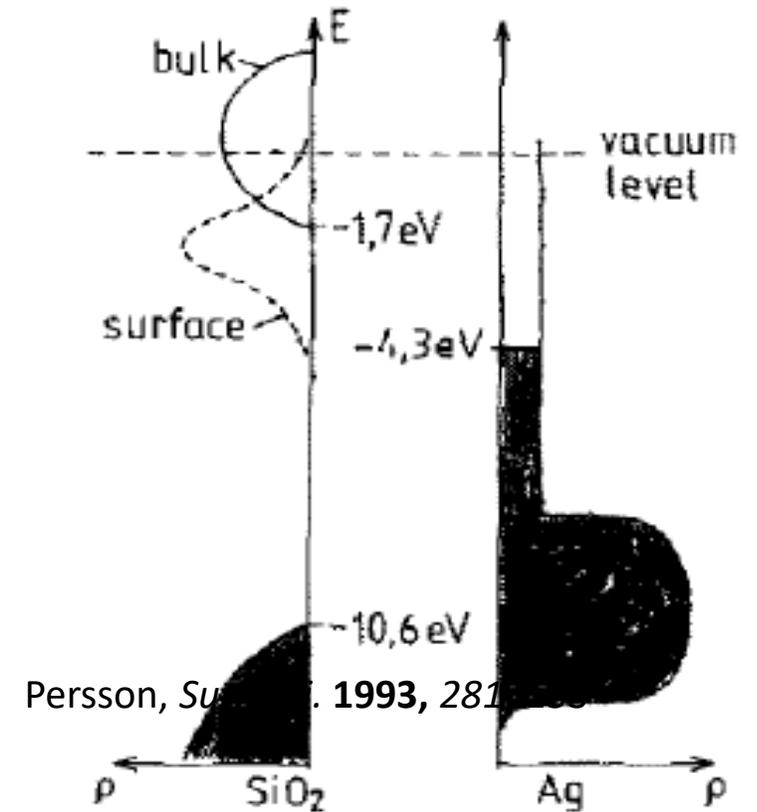
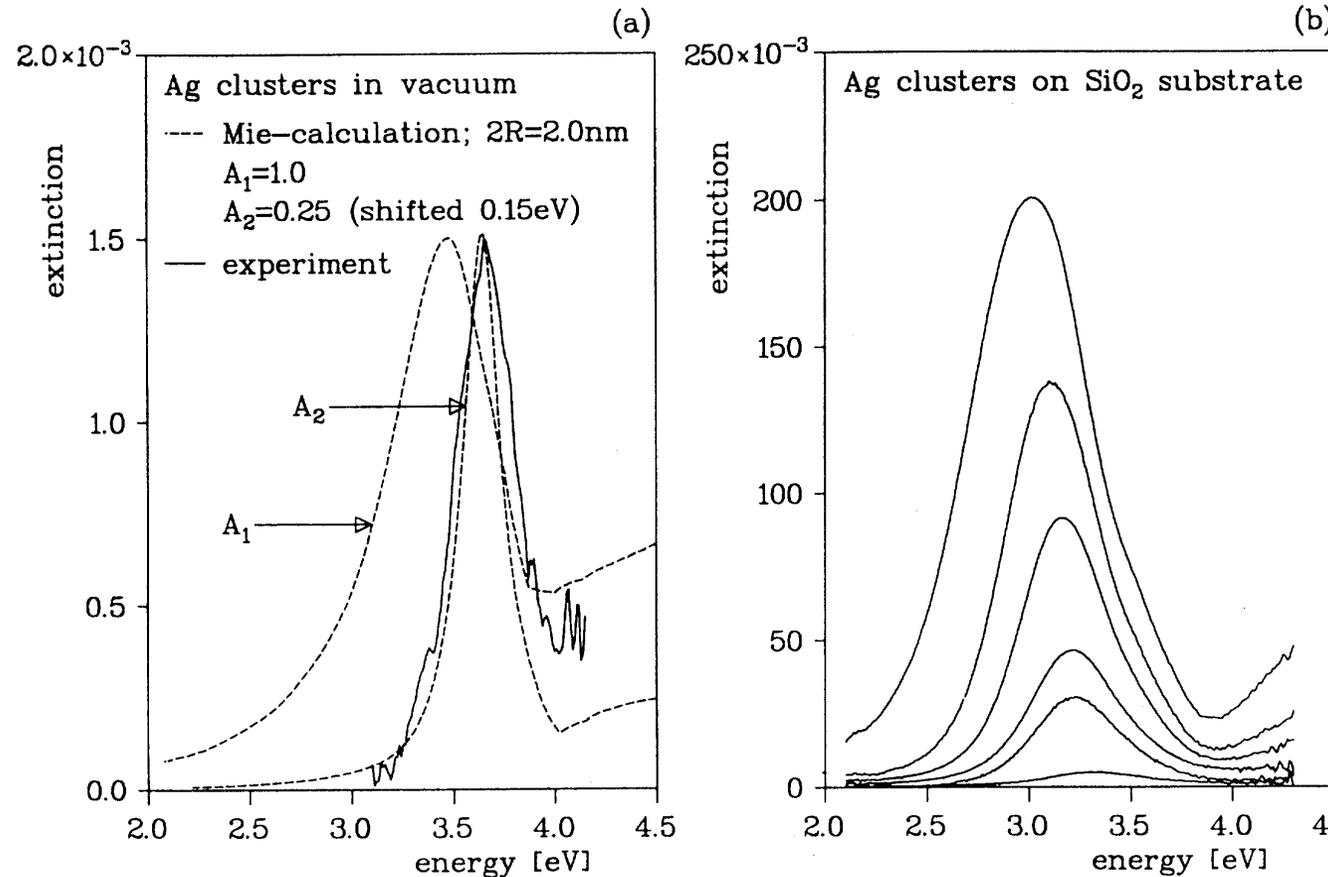
# Additional plasmon decay – chemical interface damping (CID)



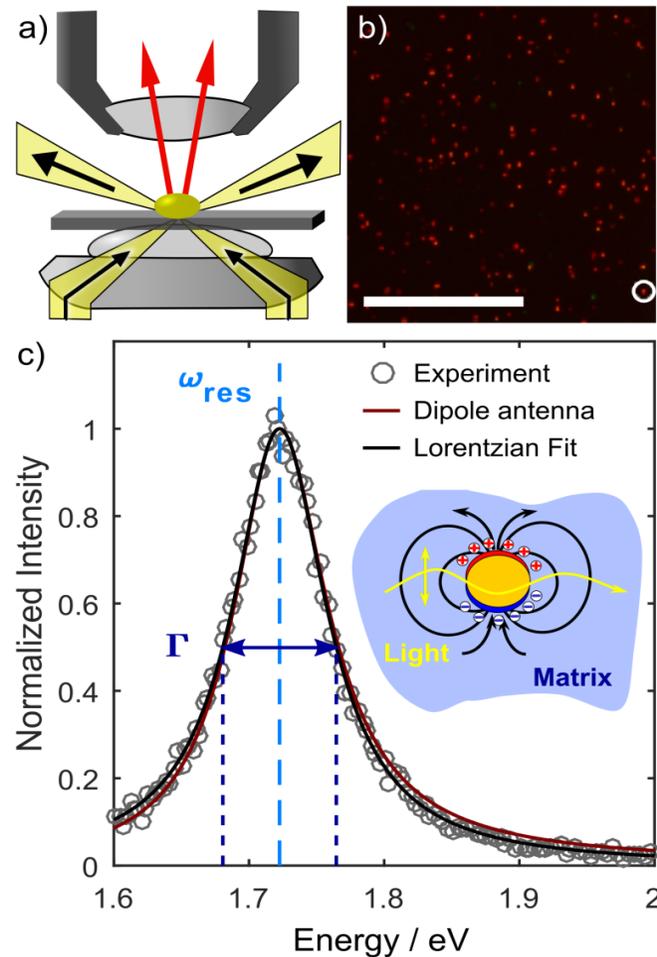
# Additional plasmon decay – chemical interface damping (CID)

$$\Gamma = \gamma_b + \Gamma_{\text{rad}} + \Gamma_{\text{surf}} + \Gamma_{\text{CID}}$$

$$\Gamma_{\text{total}} = \gamma_b + 2\hbar\pi V + \frac{A_{\text{surf}} \cdot v_F}{l_{\text{eff}}} + \Gamma_{\text{CID}}$$

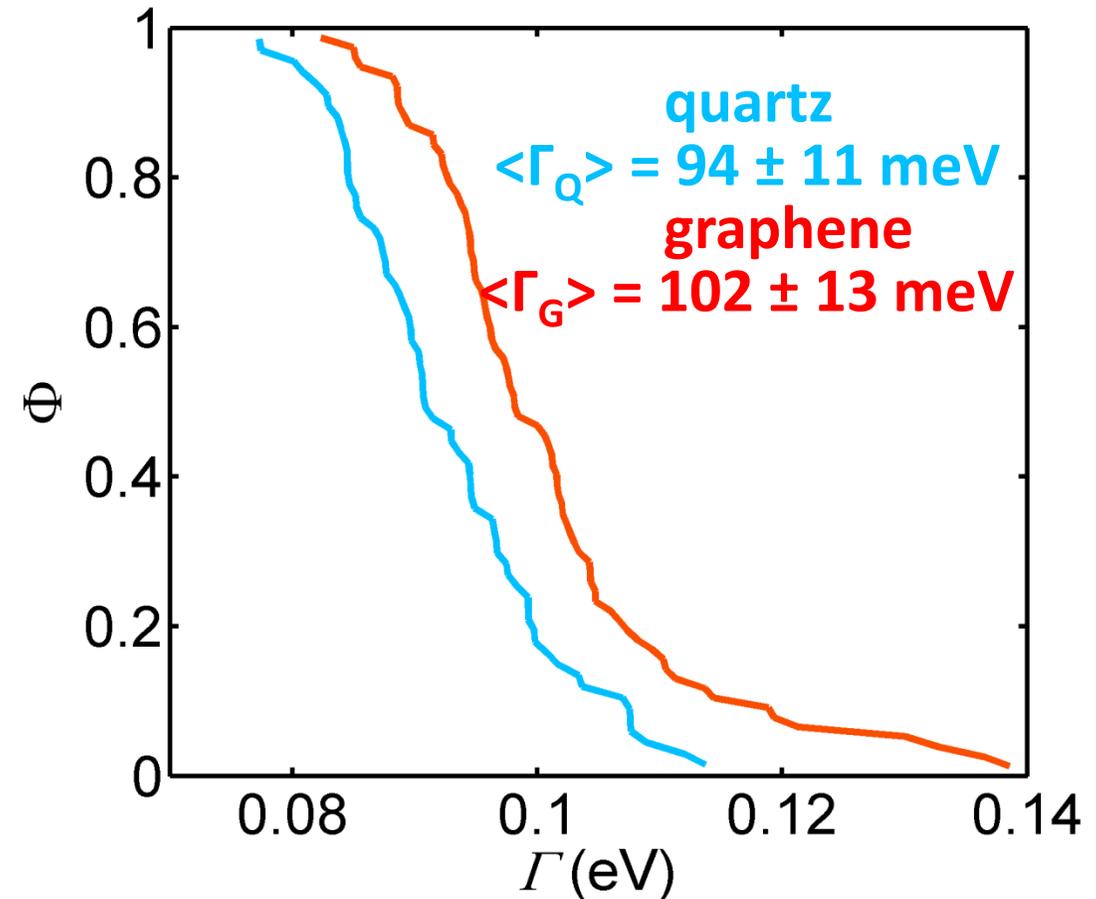


# Homogeneous Linewidth from Single Particle Spectroscopy



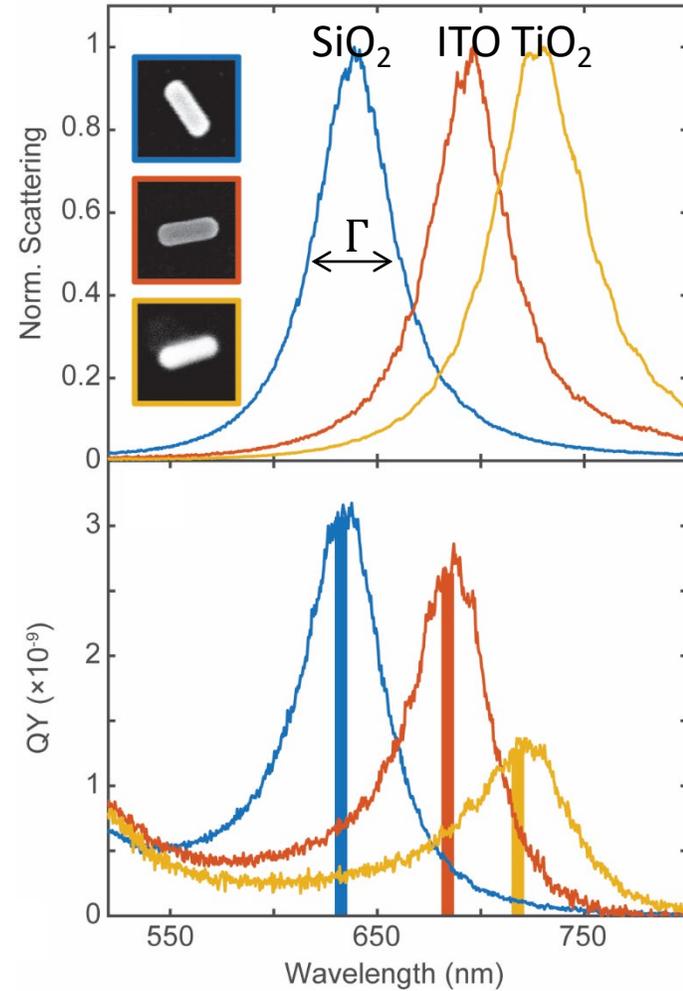
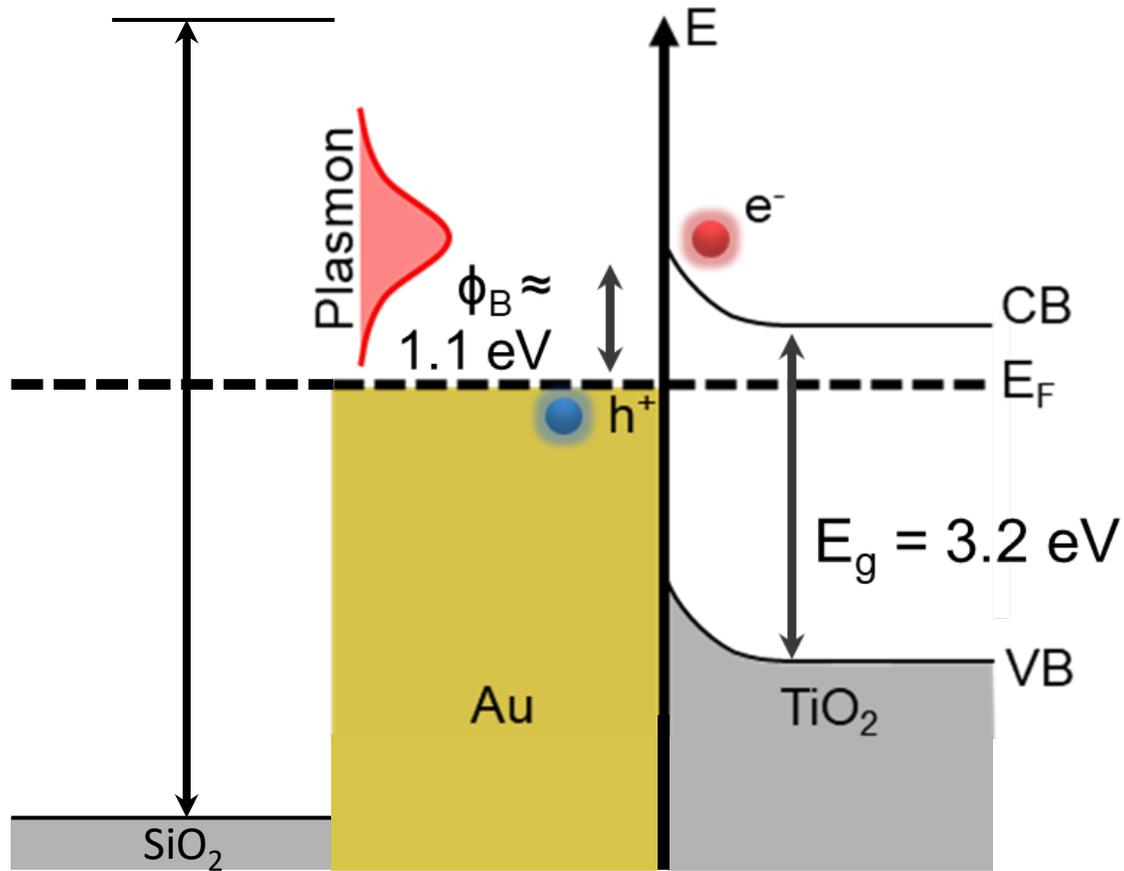
Foerster, Link, Soennichsen et al.,  
ACS Nano 11, 2886 (2017)

## CID of gold nanorods on graphene



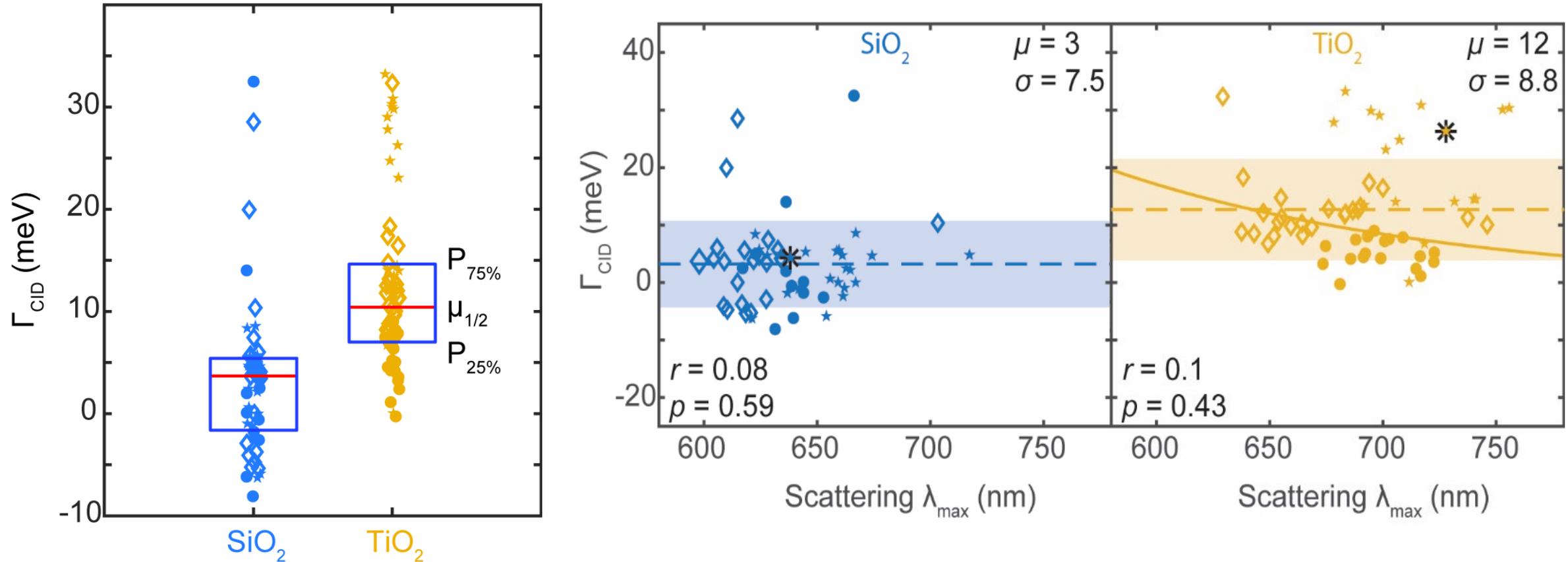
Hoggard, Chang, Ajayan. Link et al., ACS Nano 7, 11209 (2013)

# Au-TiO<sub>2</sub> interfaces: Chemical interface damping of gold nanorods on SiO<sub>2</sub> and TiO<sub>2</sub> substrates

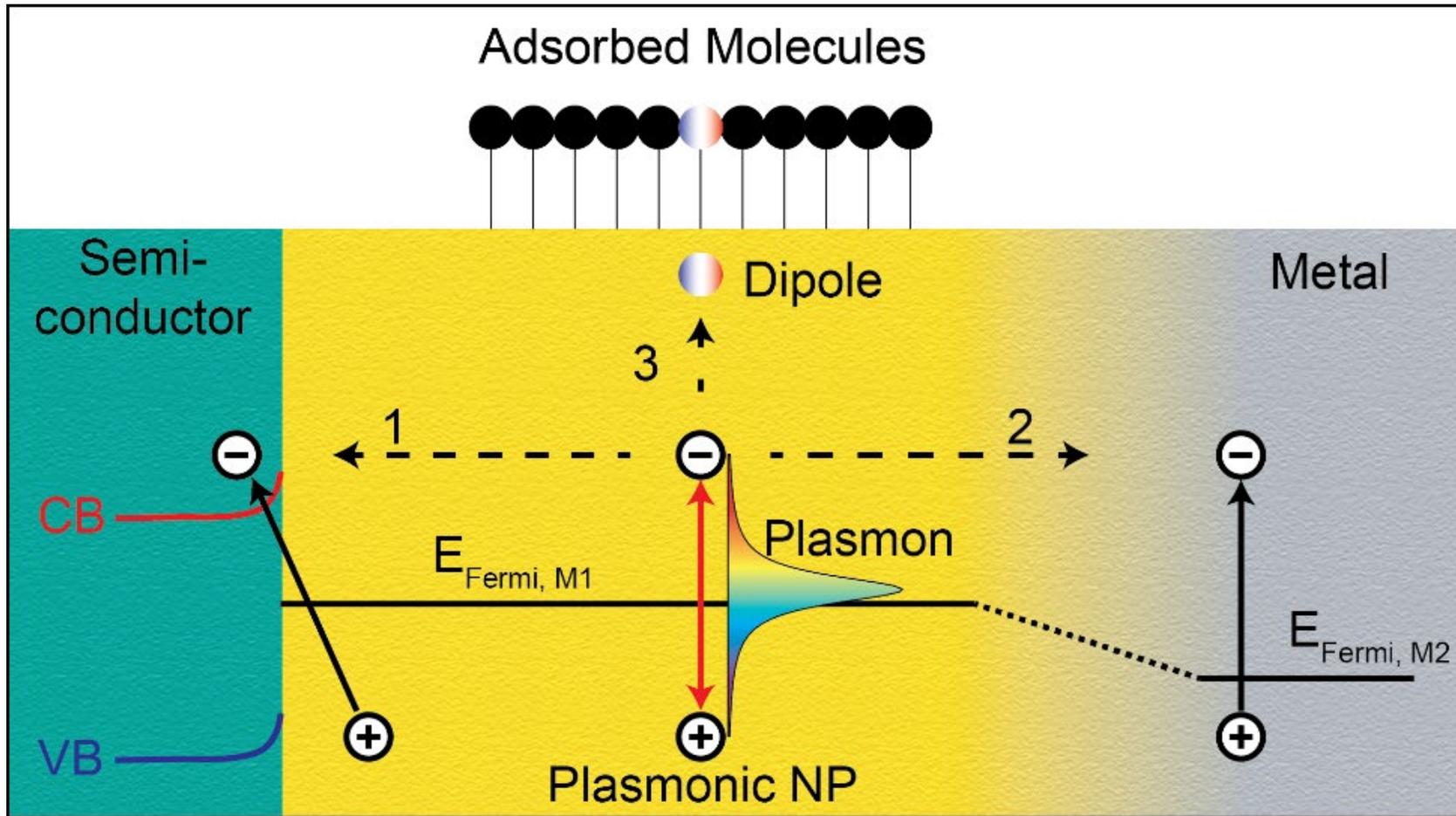


# Chemical interface damping reveals plasmon energy independent charge transfer for the TiO<sub>2</sub> substrate

After correction for bulk and radiation damping based on SEM correlated nanorod size



# Only chemical Interface damping is insufficient to prove plasmon induced *direct* charge transfer

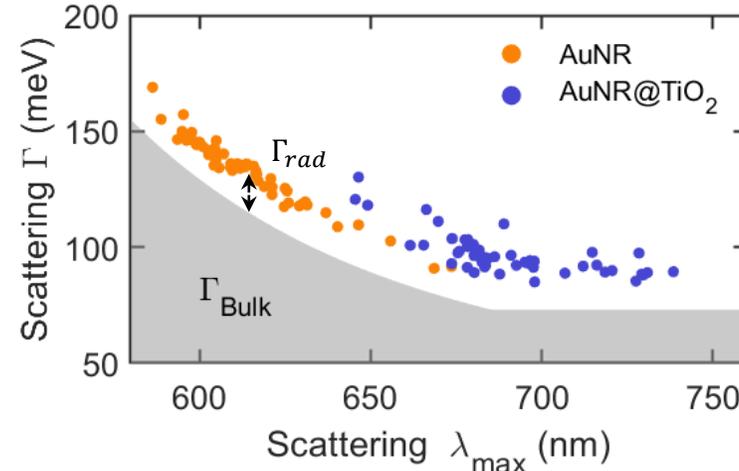
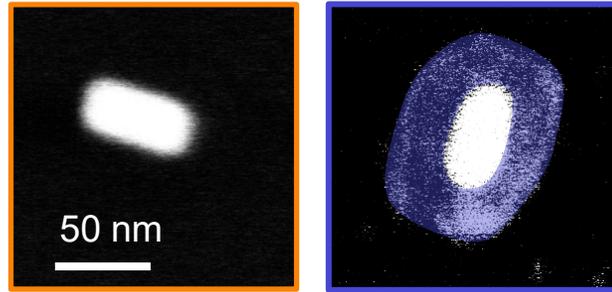


**Additional plasmon decay mechanism:**  
-Charge transfer  
-Energy transfer  
-Surface induced dipole scattering

ACS Nano 7, 11209 (2013)  
ACS Nano, 11, 2886 (2017)  
ACS Nano 11, 12346 (2017)  
J. Colloid Interface Sci. 532, 143 (2018)  
J. Phys. Chem. C 122, 19116 (2018)  
Sci. Adv. 5, av0704 (2019)  
Nano Lett. 20, 3338 (2020)  
ACS Nano 15, 9522 (2021)  
Acc. Chem. Res. 54, 1950 (2021)  
J. Chem. Phys. 156, 064702 (2022)  
ACS Nano 17, 18280 (2023)  
J. Phys. Chem. Lett. 14, 8235 (2023,)  
Sci. Adv. 10, eadp3353 (2024)

**Need complementary method: IR transient absorption spectroscopy (to give total charge injection)**

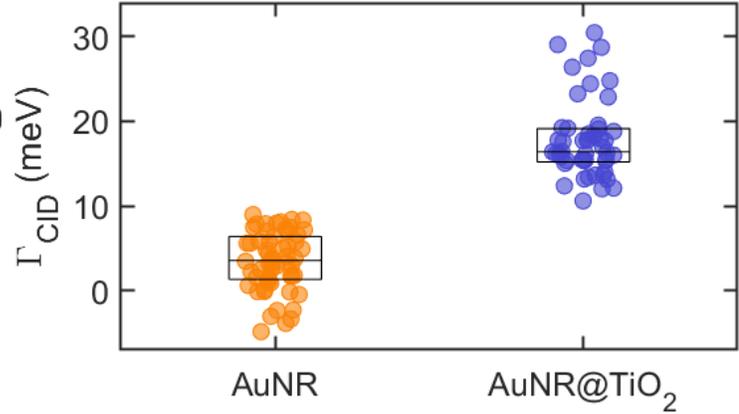
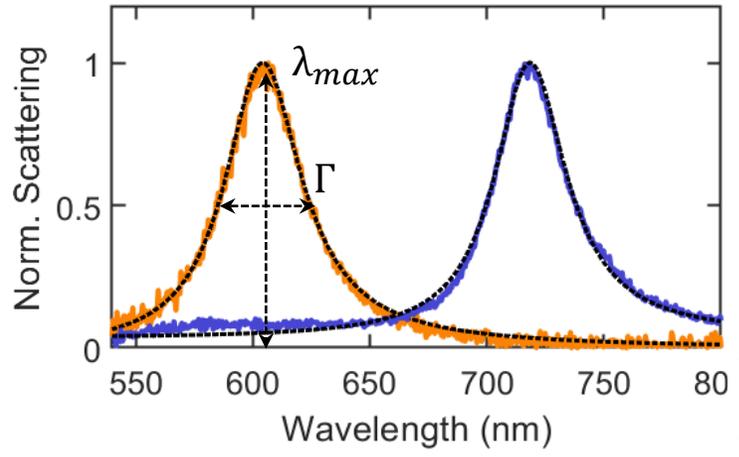
# Gold nanorods overcoated with a TiO<sub>2</sub> shell: chemical interface damping determines the yield of *direct* electron transfer



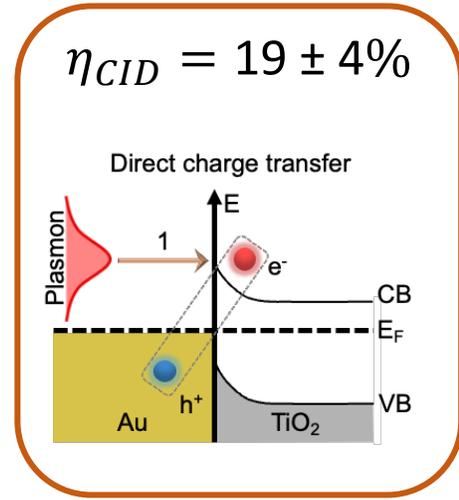
$$\Gamma_{\text{AuNR}} = \Gamma_{\text{Bulk}} + \Gamma_{\text{rad}}$$

$$\Gamma_{\text{AuNR@TiO}_2} = \Gamma_{\text{Bulk}} + \Gamma_{\text{rad}} + \Gamma_{\text{CID}}$$

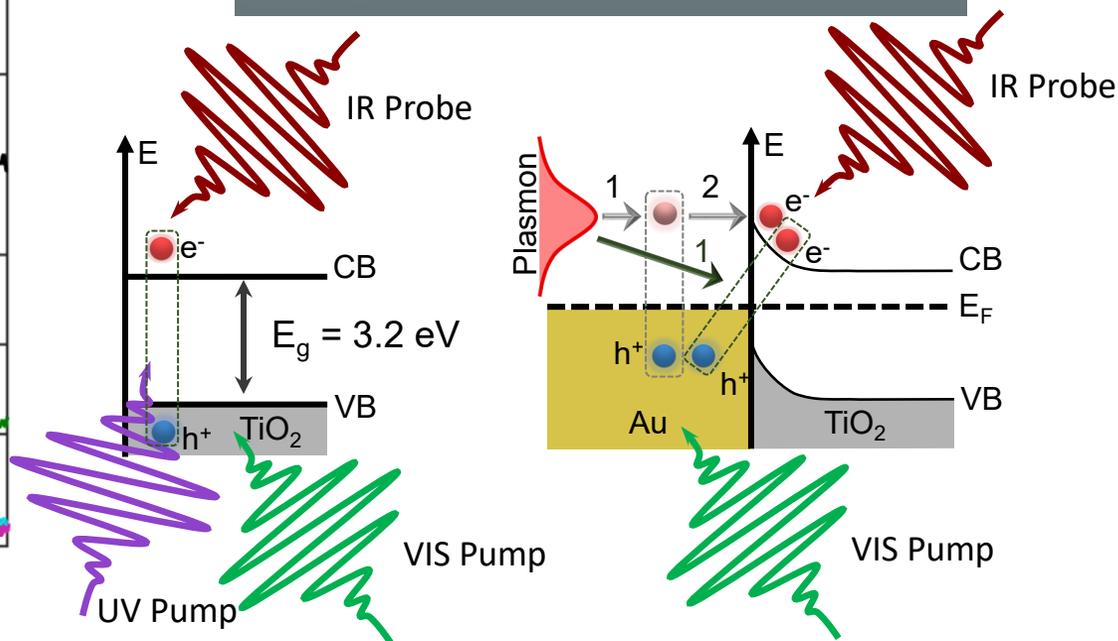
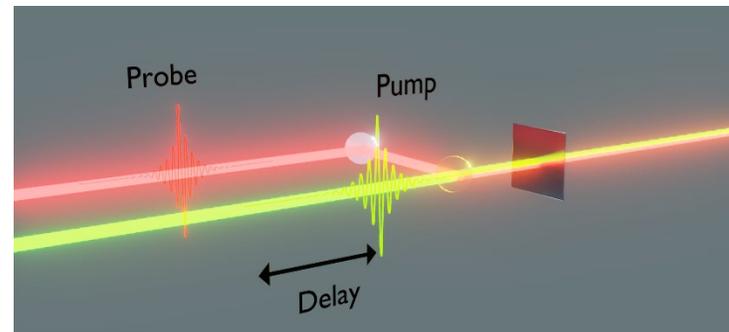
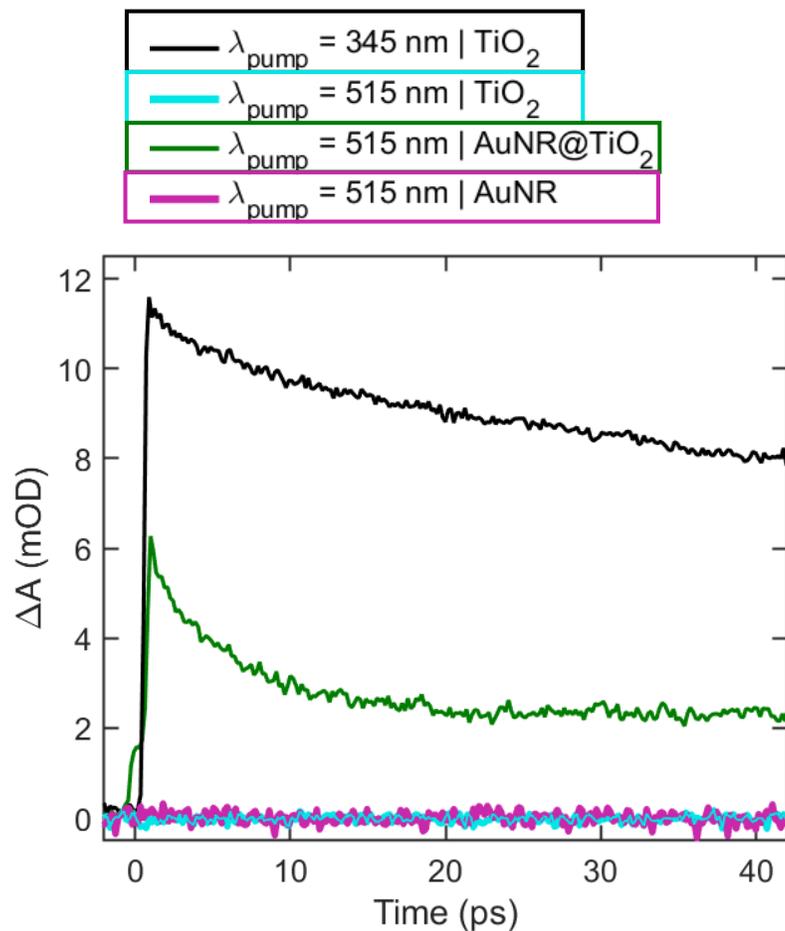
$$\eta_{\text{CID}} = \frac{\Gamma_{\text{CID}}}{\Gamma}$$



	$\Gamma_{\text{CID}}$ (meV)
AuNR	$3.4 \pm 3.5$
AuNR@TiO <sub>2</sub>	$20.7 \pm 4.7$

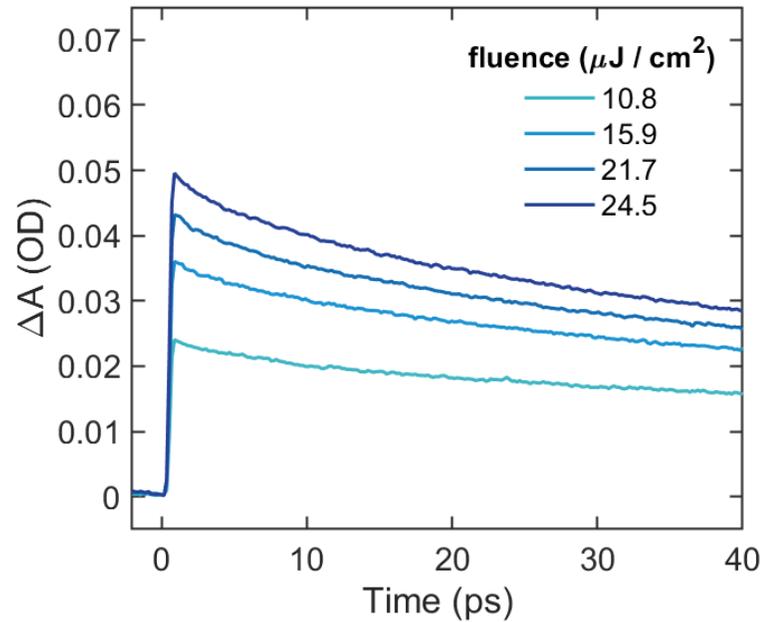


# IR transient absorption spectroscopy probes the *total*/free carriers within the TiO<sub>2</sub> conduction band

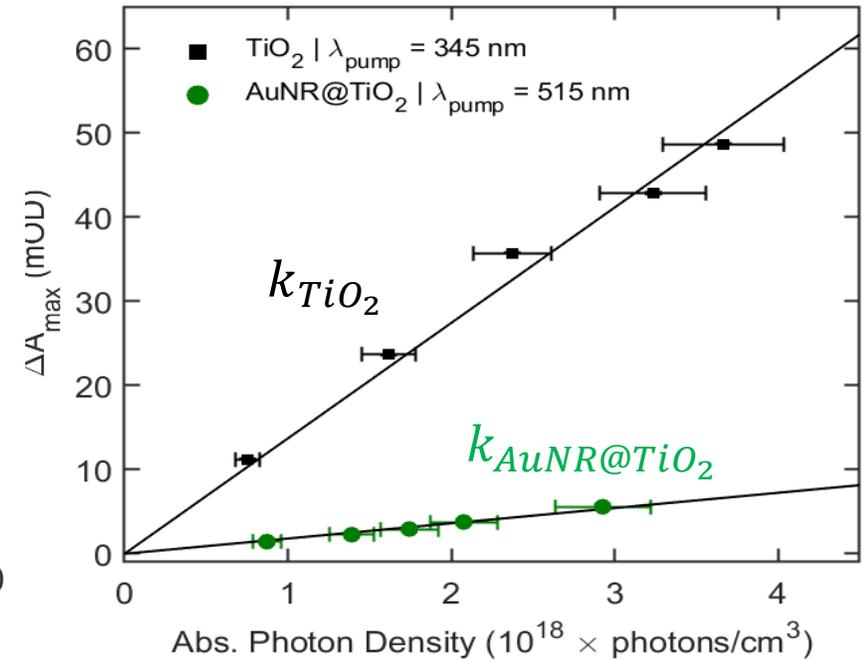
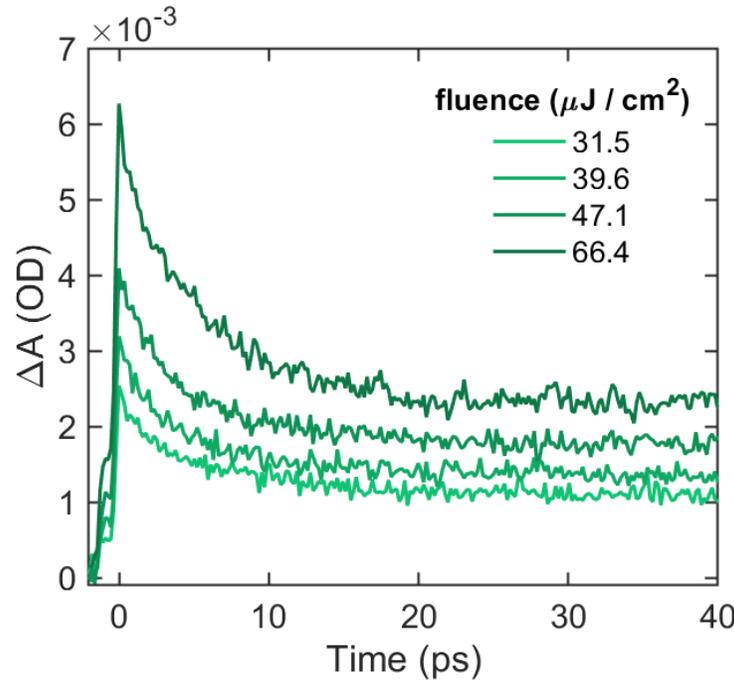


# IR transient absorption (TA) spectroscopy probes the *total*/free carriers within the TiO<sub>2</sub> conduction band

TiO<sub>2</sub> – 345-nm excitation

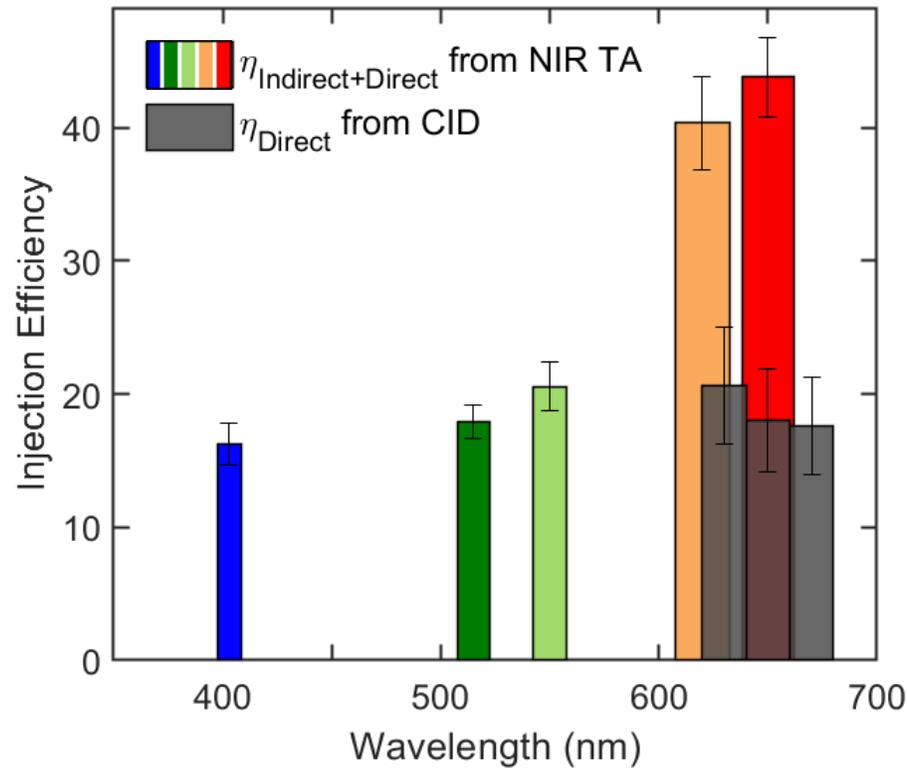


AuNR@TiO<sub>2</sub> – 515-nm excitation

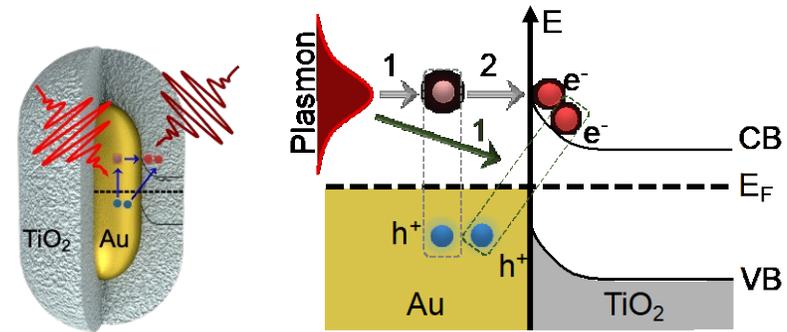


$$\eta_{inj} = \eta_{direct+indirect} = \frac{k_{AuNR@TiO_2}}{k_{TiO_2}} = 15 \pm 6 \%$$

# Injection efficiency as a function of excitation wavelength: *direct* decay pathway only possible at plasmon resonance



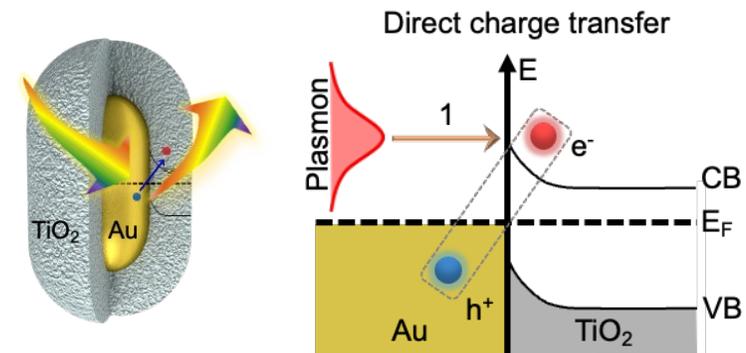
At plasmon excitation:



$$\eta_{\text{direct+indirect}} = 44 \pm 3\%$$

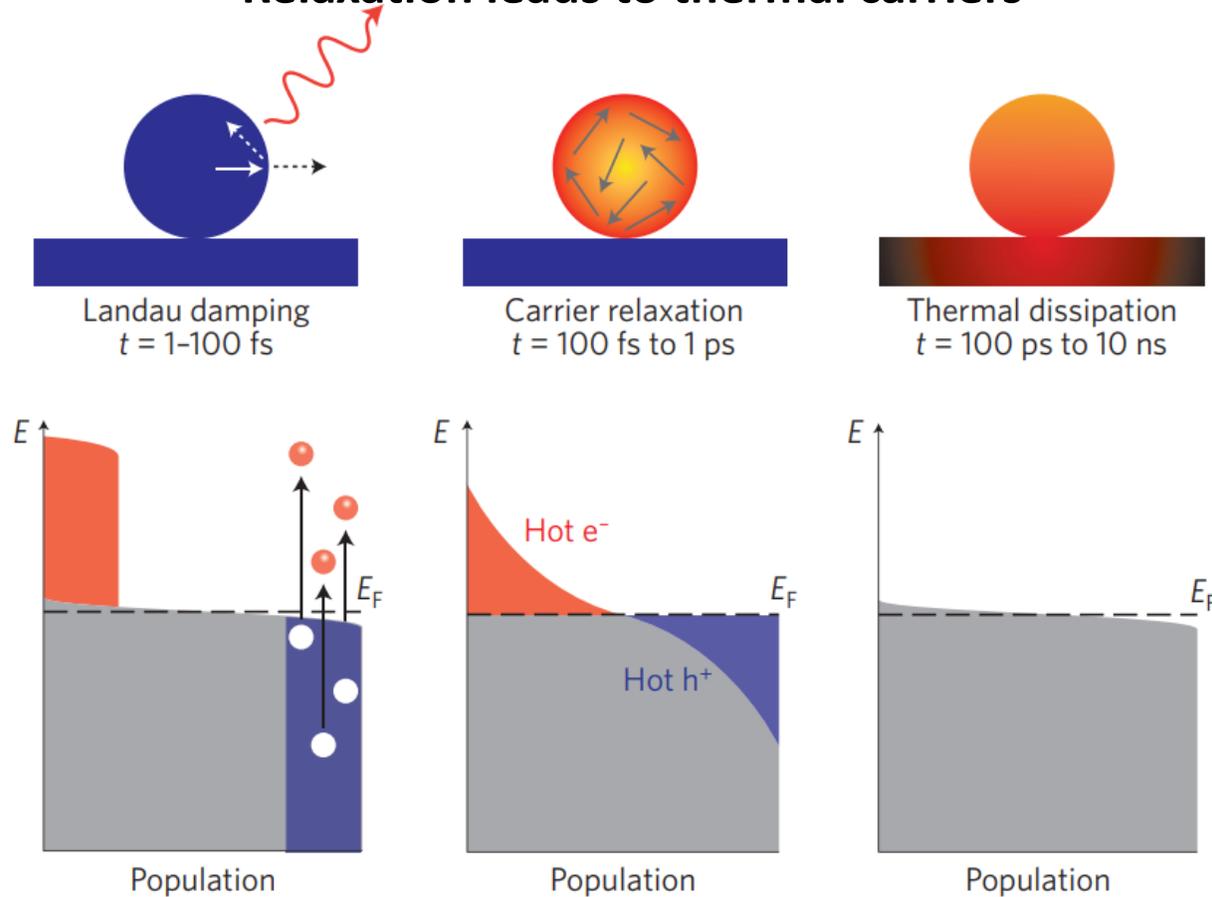
Furube et al.: 40%

J. Am. Chem. Soc. 129, 14852 (2007)



# Dynamics of metal excited carriers: Ultrafast visible pump-probe spectroscopy

## Relaxation leads to thermal carriers



Brongersma, Halas, and Nordlander, *Nat. Nanotechnol.*, **2015**, *10*, 25

JOURNAL OF CHEMICAL PHYSICS

VOLUME 111, NUMBER 3

15 JULY 1999

## Electron dynamics in gold and gold–silver alloy nanoparticles: The influence of a nonequilibrium electron distribution and the size dependence of the electron–phonon relaxation

S. Link and C. Burda

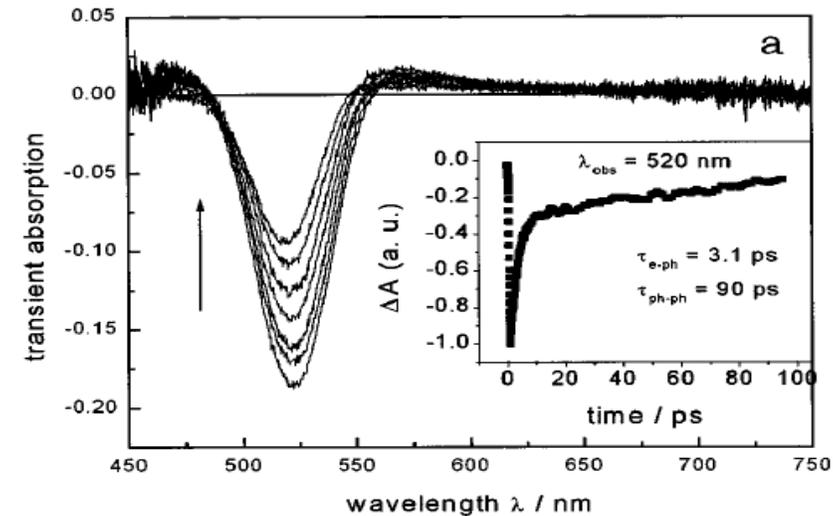
*Laser Dynamics Laboratory, School of Chemistry and Biochemistry, Georgia Institute of Technology, Atlanta, Georgia 30332-0400*

Z. L. Wang

*School of Materials Science and Engineering, Georgia Institute of Technology, Atlanta, Georgia 30332-0400*

M. A. El-Sayed<sup>a)</sup>

*Laser Dynamics Laboratory, School of Chemistry and Biochemistry, Georgia Institute of Technology, Atlanta, Georgia 30332-0400*



# Dynamics of metal excited carriers: Ultrafast pump-probe spectroscopy

## Two-temperature model

$$\tau_{e-ph} = \gamma(\Delta T + T_0)/g$$



$$\tau_{e-ph} = \gamma\Delta T/g + \gamma T_0/g$$

$\tau_{e-ph} \propto \Delta T \rightarrow$ 

pump power

+

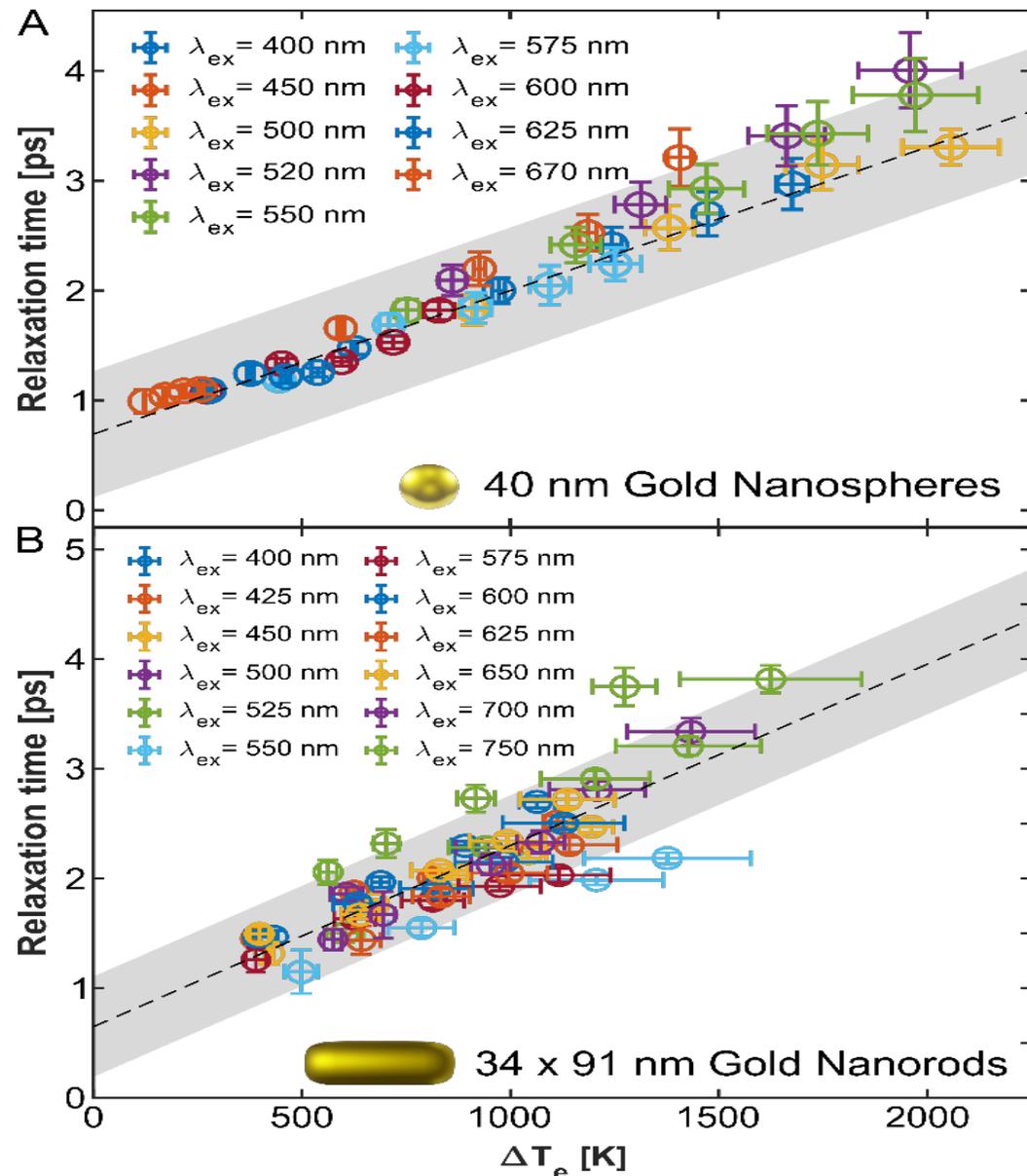
absorption cross section

$\gamma$ : electron heat capacity

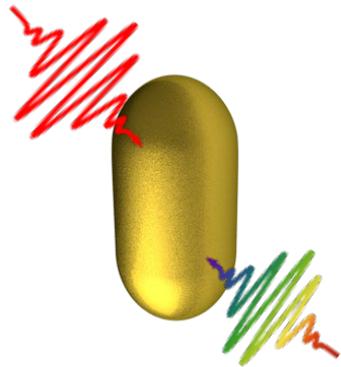
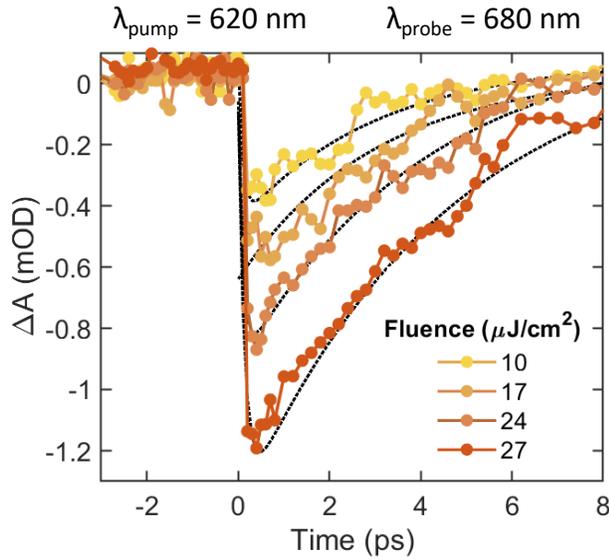
$g$ : electron-phonon coupling constant

$T_0$ : ambient temperature

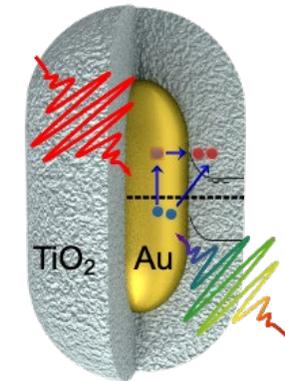
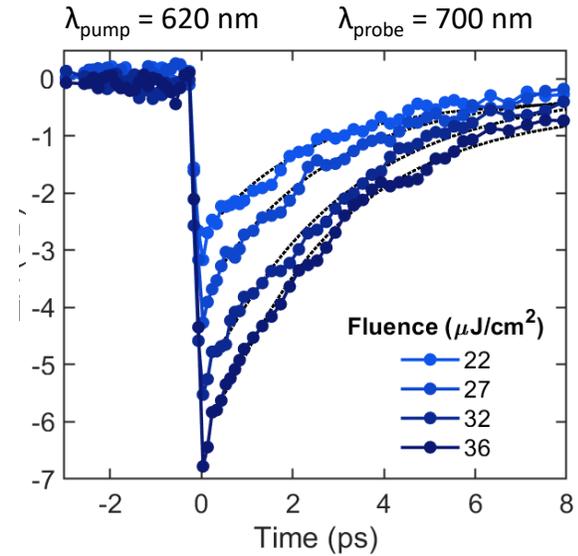
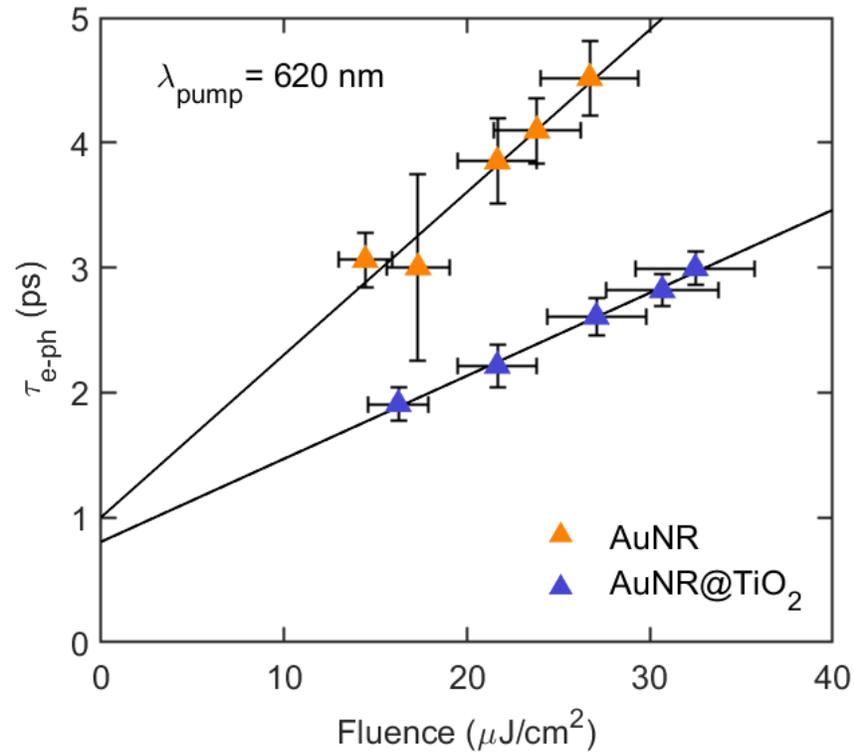
$\Delta T$ : increase of the electronic temperature



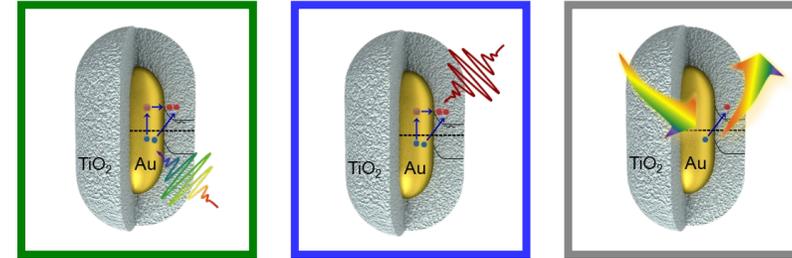
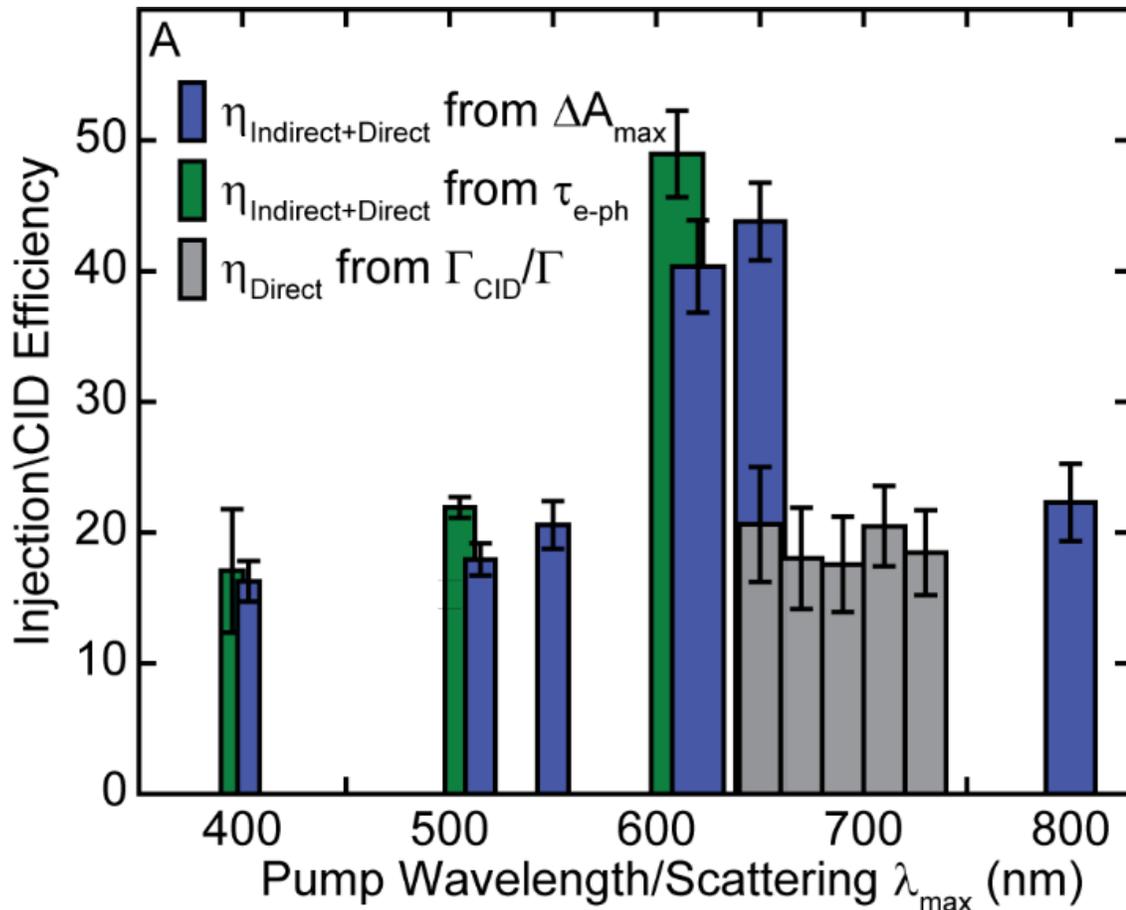
# Visible transient absorption spectroscopy reveals charge transfer through changes in electron-phonon scattering



Comparing slopes indicates that AuNR@TiO<sub>2</sub> becomes half as hot, implying ~ 50% total charge injection



# Both direct and sequential charge transfer occur – plasmon enhancement through chemical interface damping



- VIS transient absorption data determines the amount of absorbed energy that is lost to the  $\text{TiO}_2$
- NIR transient absorption spectroscopy probes the total charge injection via free electron absorption in the  $\text{TiO}_2$  conduction band
- Single-particle spectroscopy quantifies charge injection via plasmon decay only

**Plasmon damping into interfacial charge separated states is a significant/efficient decay pathway**

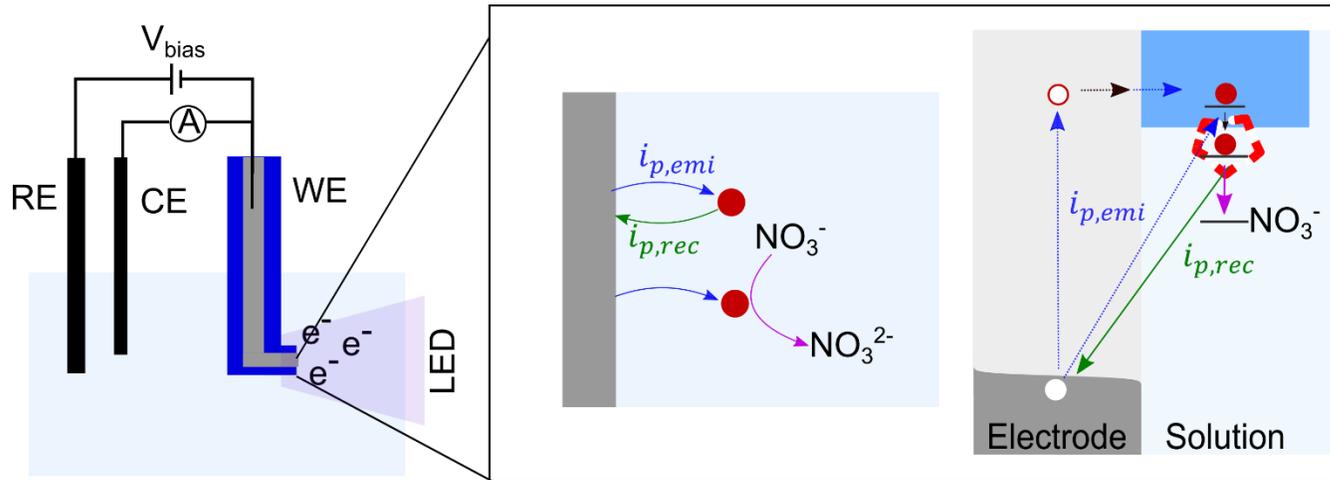
# Outline

1) Charge transfer at metal – semiconductor interfaces

**2) Photoemission into water**

# Photoemission can be detected electrochemically

## Electron scavengers prevent recombination



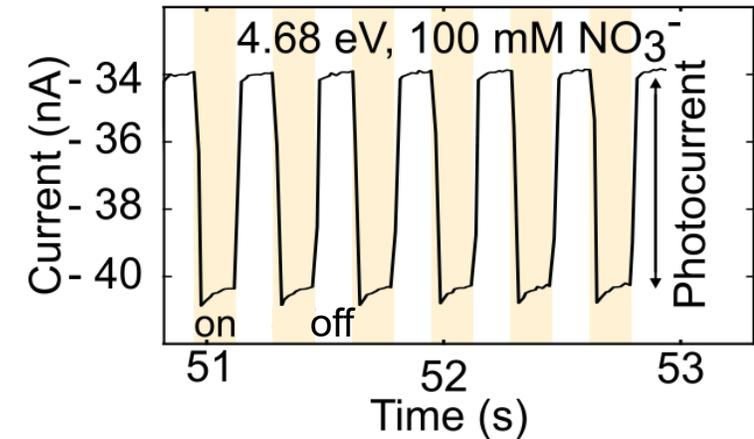
Emission:  $M + \hbar\omega \rightarrow e^- + h^+$   $i_{p,emi}$

Reaction:  $e^- + NO_3^- \rightarrow NO_3^{2-}$

Recombination:  $e^- + h^+(M) \rightarrow M$   $i_{p,rec}$

Overall:  $i_p = i_{p,emi} + i_{p,rec}$

## Photocurrent gives emission yield



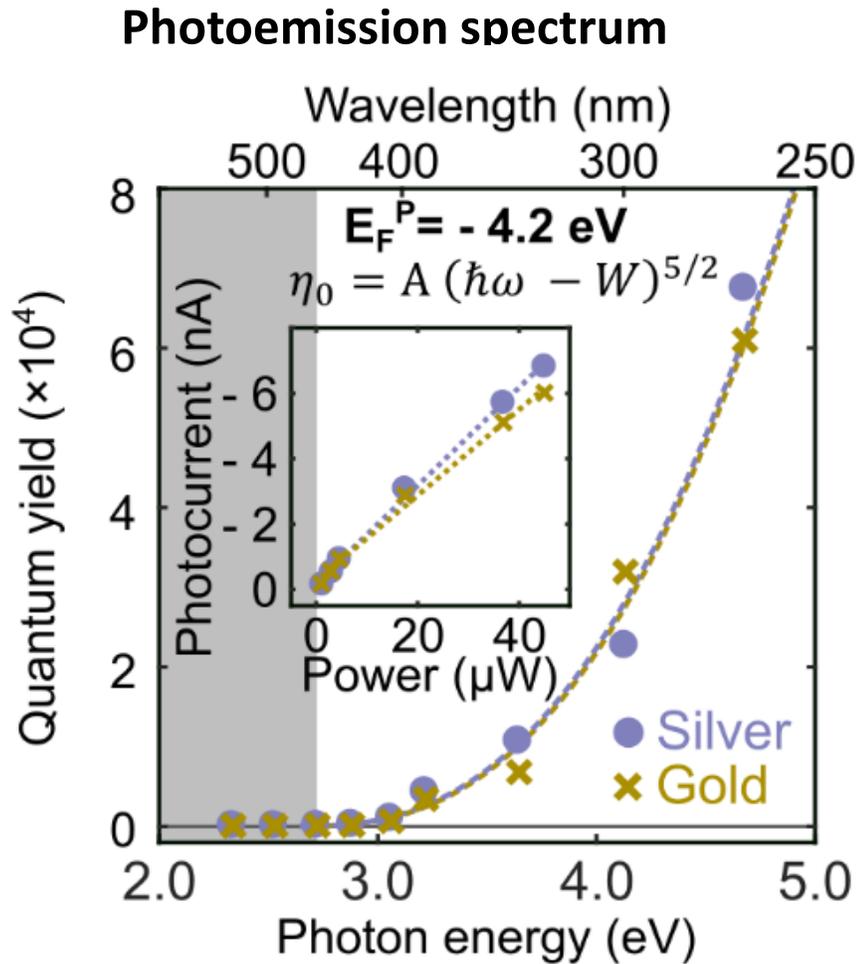
- $NO_3^-$  prevents recombination
- Photocurrent proportional to photoemission yield:

$$i_p = n_{e_{(aq)}} F$$

( $F = 96485 \text{ A s mol}^{-1}$ )

External quantum yield: 
$$\eta = \frac{i_p (A) \times \hbar\omega (eV)}{P (W)}$$

# Emission from smooth electrodes follows 5/2 power law



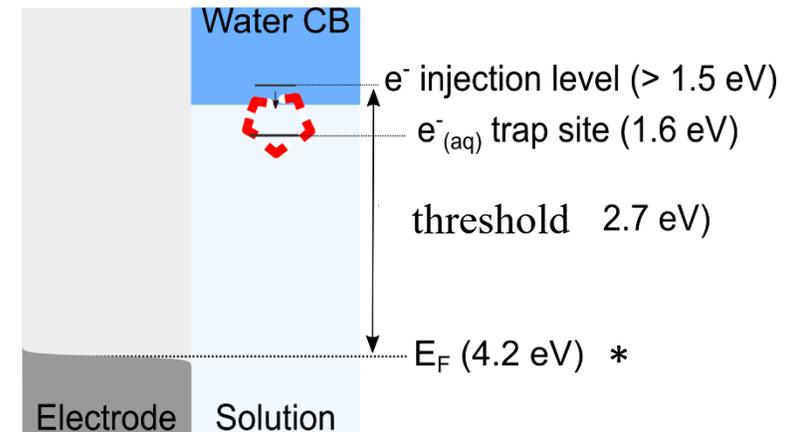
Quantum efficiency depends on excess energy above threshold:

$$\eta_0 = A (\hbar\omega - W)^{5/2}$$

Fit reveals threshold:

$$W = 2.7 \text{ eV}$$

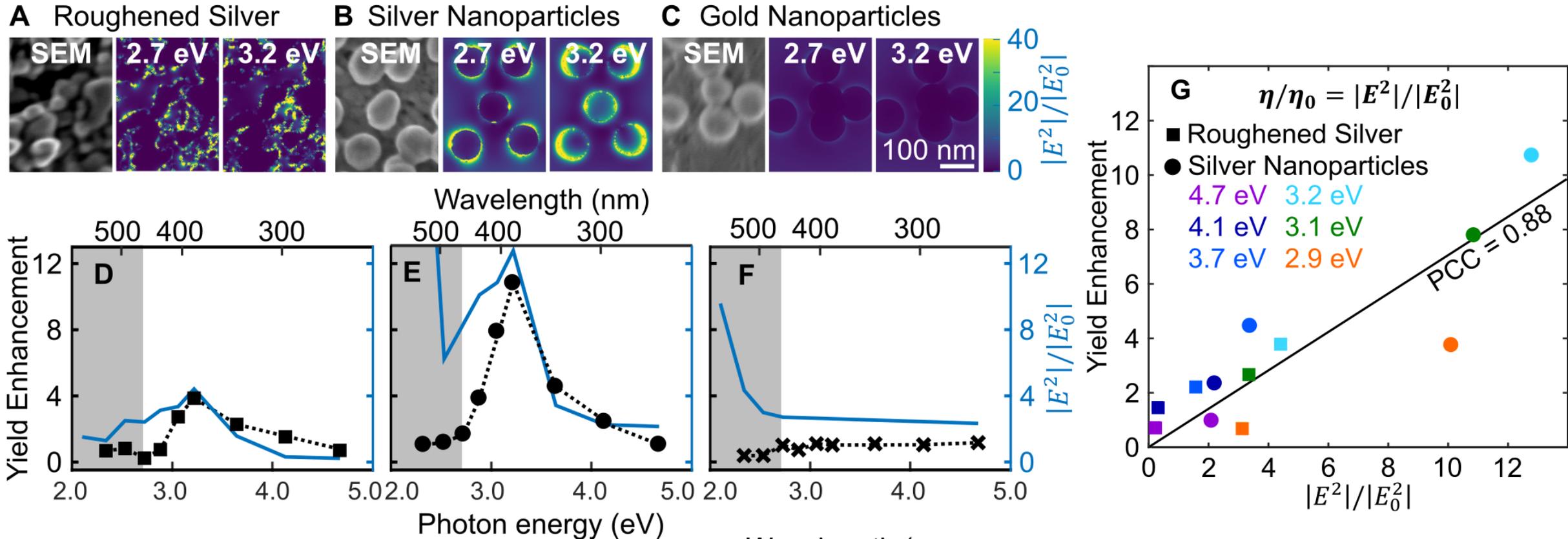
Threshold agrees with  $e^-$  injection level:



\* 4.2 eV = - 0.3 V vs SHE



# Emission scales with field enhancement

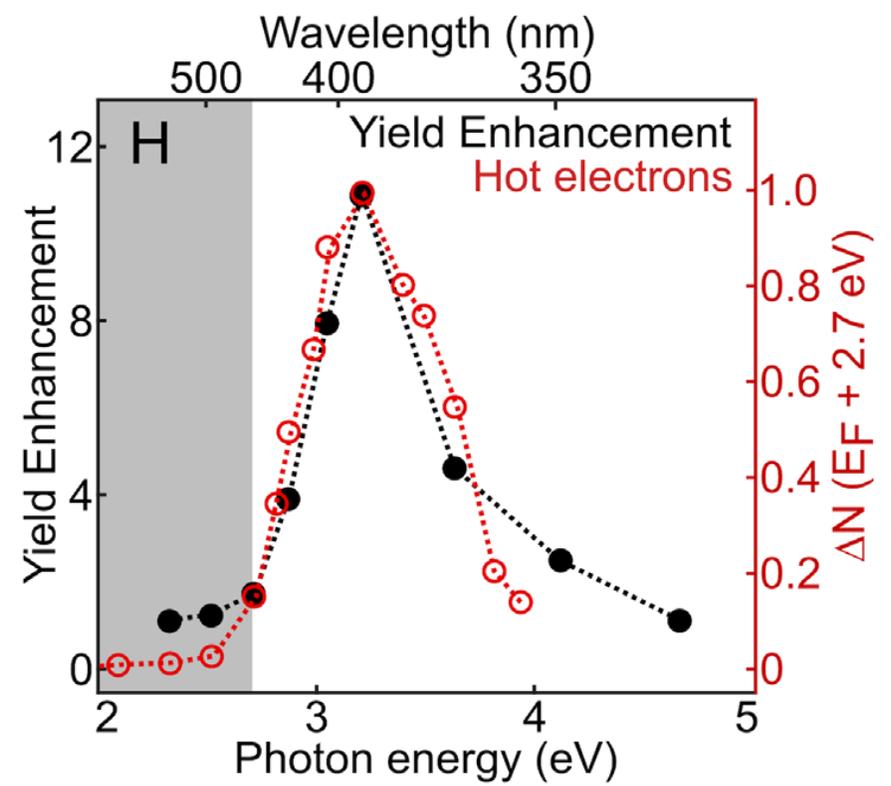


**Photoemission scales linearly with field enhancement**

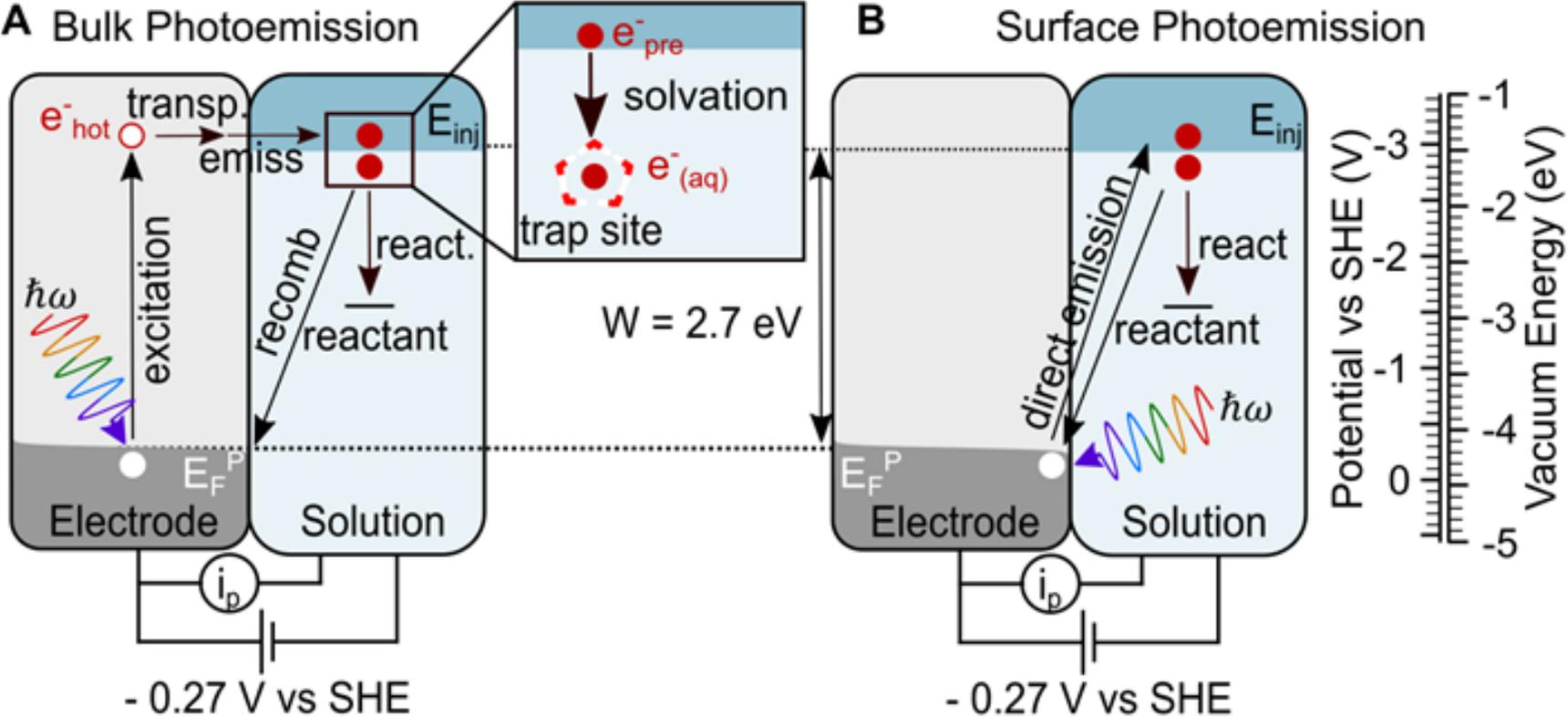
# Plasmons produce solvated electrons through field-enhanced hot electron generation in an indirect bulk emission process

Field-enhancement increases generation of hot carriers

$$\eta_{bulk} \propto n(e^-_{hot}) \propto |E_{int}|^2$$



# Plasmons produce solvated electrons through field-enhanced hot electron generation in an indirect bulk emission process



Hot  $e^-$  generation  
 Hot  $e^-$  transport to interface  
 Emission across interface

Direct injection through surface  
 scattering of  $e^-$  with photon

Increase yields with:  
 -Smaller nanostructures  
 -Coupled modes

Need larger potential  
 windows or higher  
 energy resonances

Al nanoparticles in organic  
 solvent: Solti, Nordlander,  
 Halas et al., *J. Am. Chem. Soc.*  
**2022**, *144*, 20183

# Conclusions

## **1) Charge transfer at metal – semiconductor interfaces**

*Plasmons open up direct charge transfer process thereby enhancing charge injection efficiency*

## **1) Photoemission into water**

*Plasmons drive solvated electron generation through enhanced fields (indirect pathway)*

**THANK YOU!!!**

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